

A SiPM-based optical readout for the ePIC dual-radiator RICH

Roberto Preghenella
INFN Bologna

iWoRiD 2024

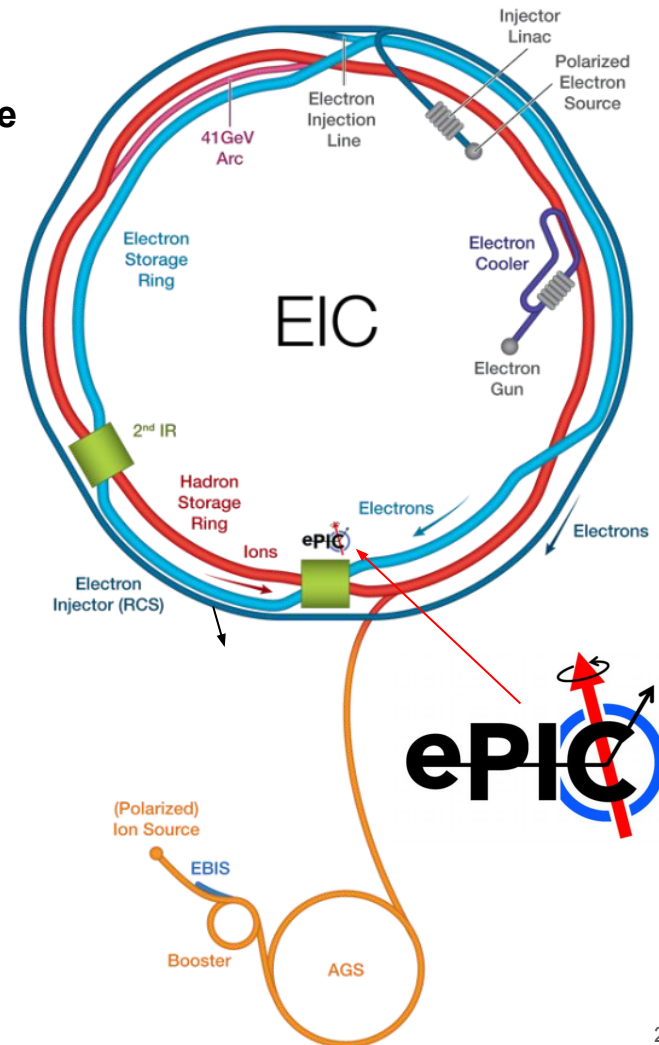
International Workshop on Radiation Imaging Detectors
30 June – 4 July 2024, Lisbon



The Electron-Ion Collider

a machine that will unlock the secrets of the strongest force in Nature
is a future electron-proton and electron-ion collider at BNL (USA)
foreseen to start operation in early 2030's

- **the major US project in the field of nuclear physics**
 - one of the most important scientific facilities for the future of nuclear and subnuclear physics
- **the world's first collider for**
 - polarised electron-proton (and light ions)
 - electron-nucleus collisions
- **will allow to explore the secrets of QCD**
 - understand origin of mass & spin of the nucleons
 - extraordinary 3D images of the nuclear structure



Particle identification at the EIC

one of the major challenges for the detector

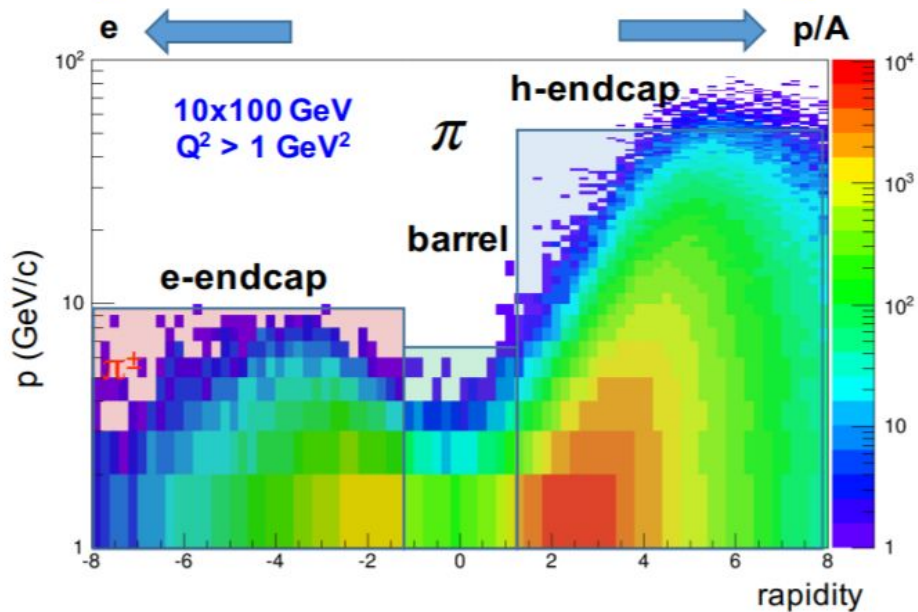
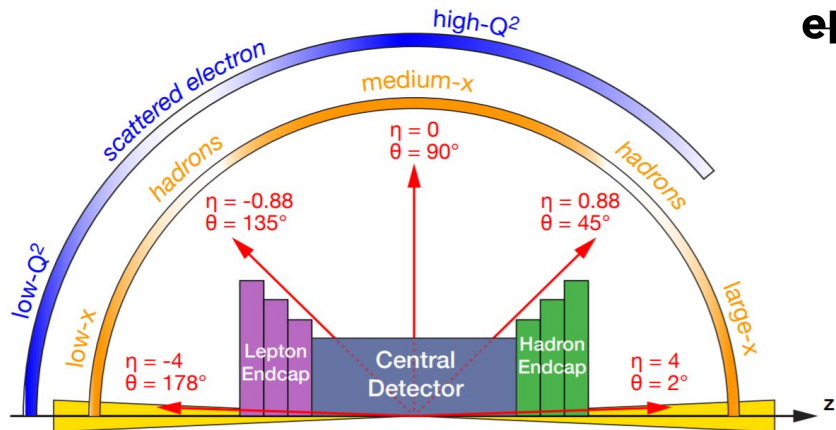
- **physics requirements**

- pion, kaon and proton ID
- over a wide range $|\eta| \leq 3.5$
- with better than 3σ separation
- significant pion/electron suppression

- **momentum-rapidity coverage**

- forward: up to 50 GeV/c
- central: up to 6 GeV/c
- backward: up to 10 GeV/c

- **demands different technologies**



The ePIC experiment

layout of the barrel detector



- **tracking**

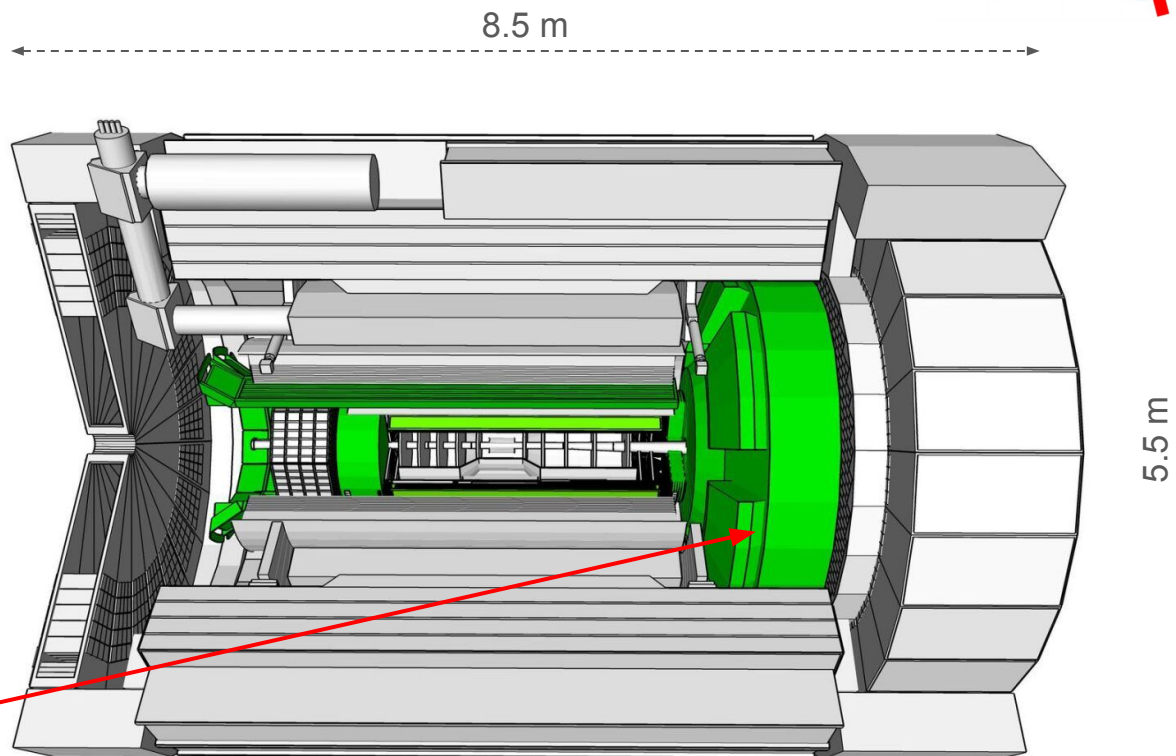
- new 1.7 T magnet
- Si-MAPS + MPGDs

- **calorimetry**

- e-side: PbWO_4 EMCal
- barrel: imaging EMCal
- h-side: finely segmented
- outer barrel HCal

- **particle ID**

- AC-LGAD TOF
- pfRICH
- hpDIRC
- **dRICH**



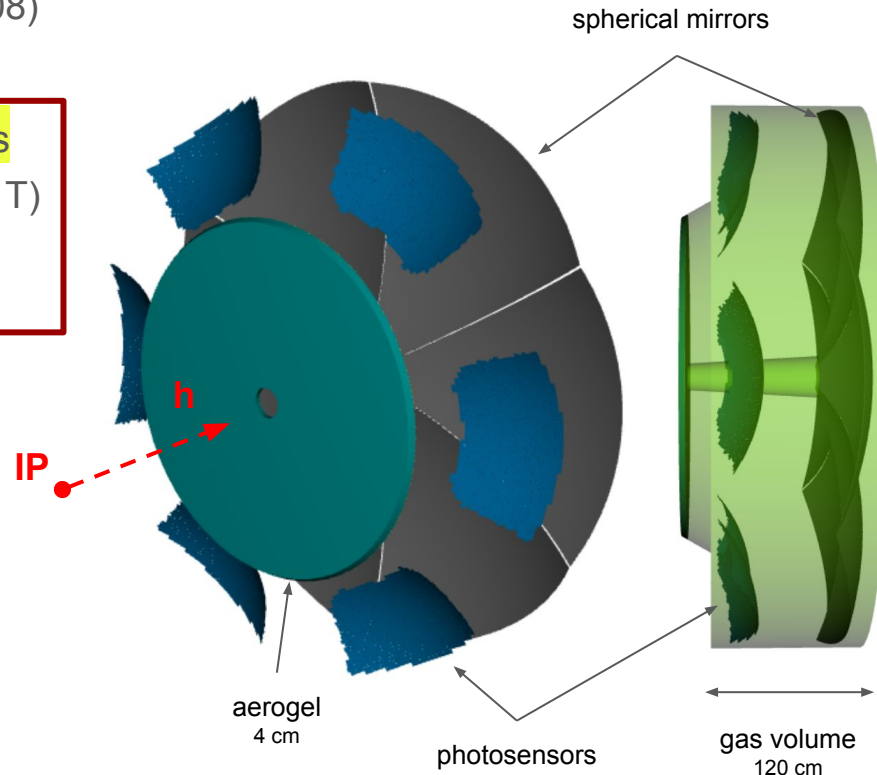
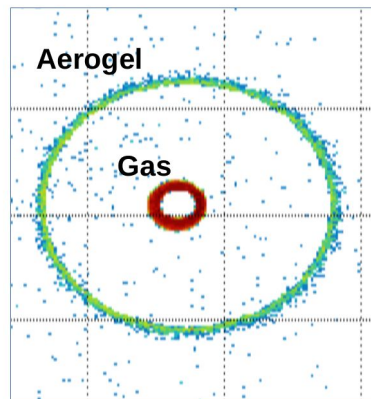
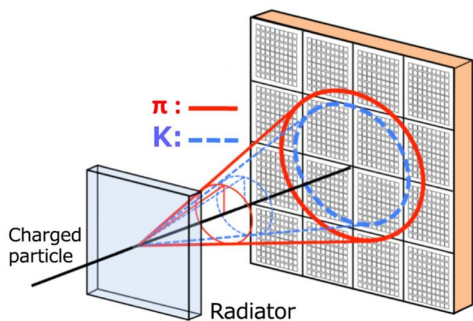
hadrons → ← electrons

The dual-radiator (dRICH) for forward PID at EIC

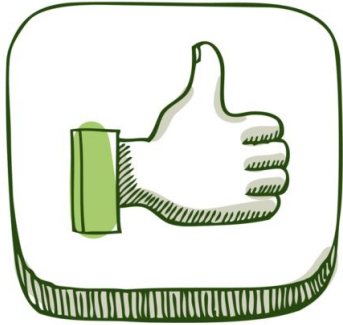
compact and cost-effective solution for broad momentum coverage at forward rapidity

$p = [3.0, 50] \text{ GeV}/c$
 $\eta = [1.5, 3.5]$
 e-ID up to $15 \text{ GeV}/c$

- **radiators:** aerogel ($n \sim 1.02$) and C_2F_6 ($n \sim 1.0008$)
- **mirrors:** large outward-reflecting, 6 open sectors
- **sensors:** $3 \times 3 \text{ mm}^2$ pixel, $\sim 3 \text{ m}^2$ of photodetectors
 - single-photon detection inside high B field ($\sim 1 \text{ T}$)
 - outside of acceptance, reduced constraints
 - **SiPM** optical readout

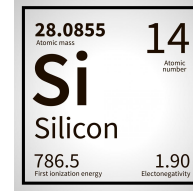


SiPM option and requirements for RICH optical readout



- **pros**

- cheap
- high photon efficiency **requirement** □
- excellent time resolution **requirement** □
- insensitive to magnetic field **requirement** □

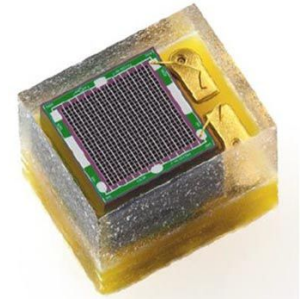


- **cons**

large dark count rates
not radiation tolerant

technical solutions and mitigation strategies

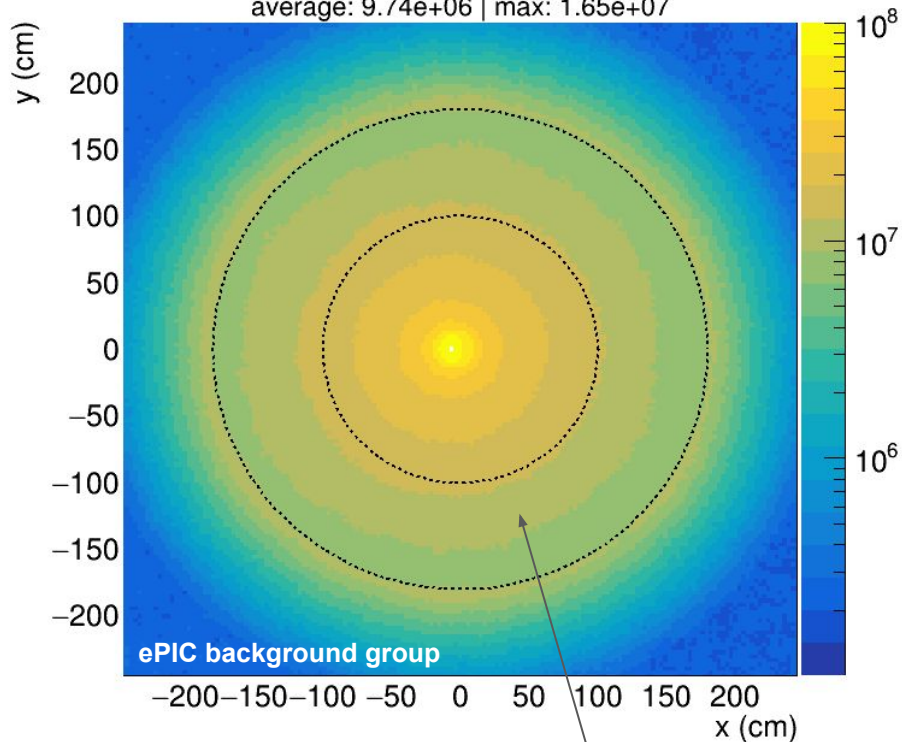
- cooling
- timing
- annealing



Radiation damage estimates

1 MEQ neutron equivalent fluence ($\text{cm}^{-2}/\text{fb}^{-1}$)
 minimum-bias PYTHIA e+p events at 10x275 GeV

average: $9.74\text{e}+06$ | max: $1.65\text{e}+07$

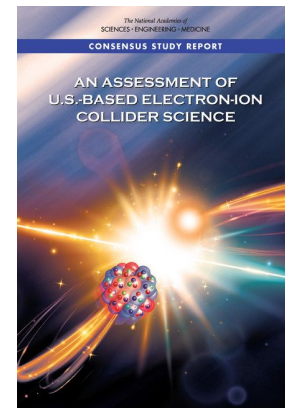


ePIC background group

Most of the key Physics goals defined by the NAS require an integrated luminosity of 10 fb^{-1} per center of mass energy and polarization setting

The nucleon imaging programme is more luminosity hungry and **requires 100 fb^{-1} per center of mass energy and polarization setting**

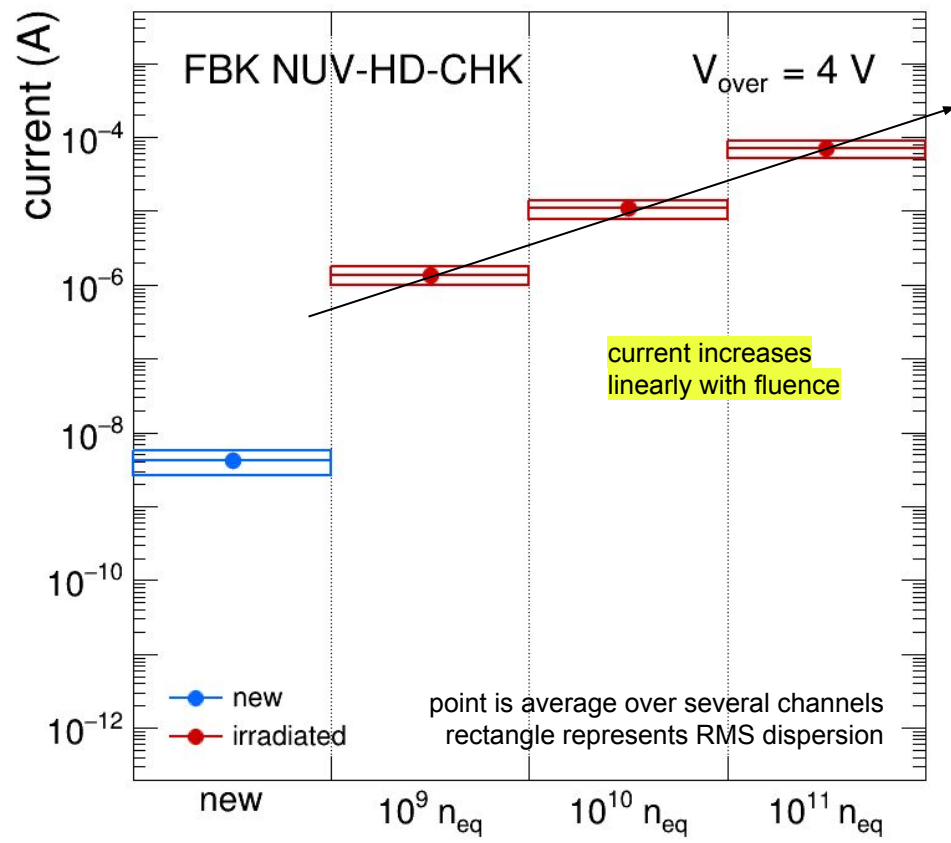
in 10-12 years the EIC will accumulate 1000 fb^{-1} integrated \mathcal{L} corresponding to an integrated fluence of $\sim 10^{10} n_{\text{eq}}/\text{cm}^2$



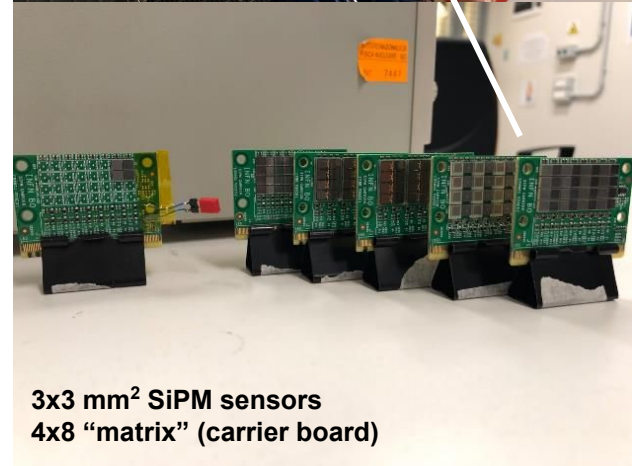
study the SiPM usability for single-photon Cherenkov imaging applications in moderate radiation environment

max fluence = $1.75 \cdot 10^7 \text{ neq}/\text{fb}^{-1}$ at the location of dRICH photosensors

Studies of radiation damage on SiPM

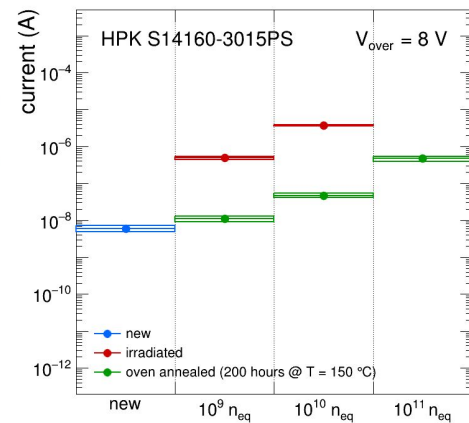
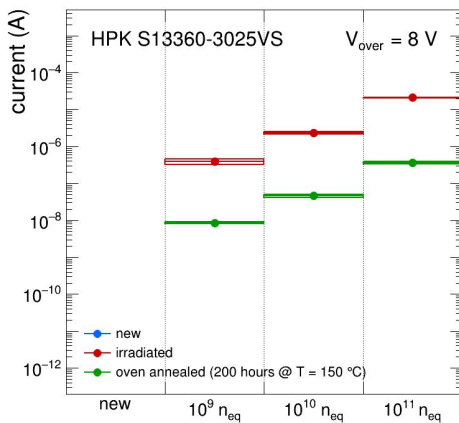
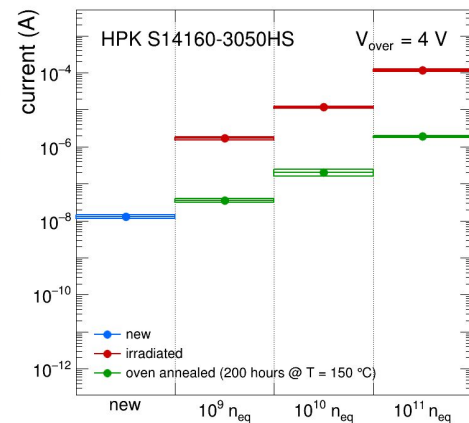
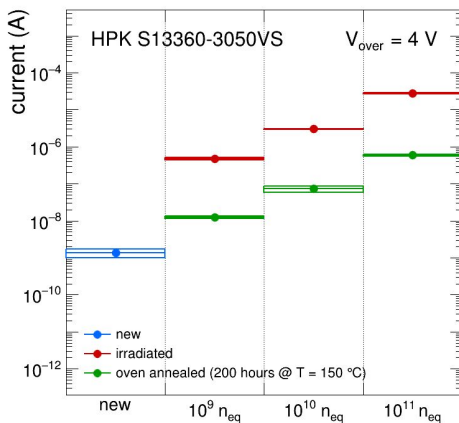
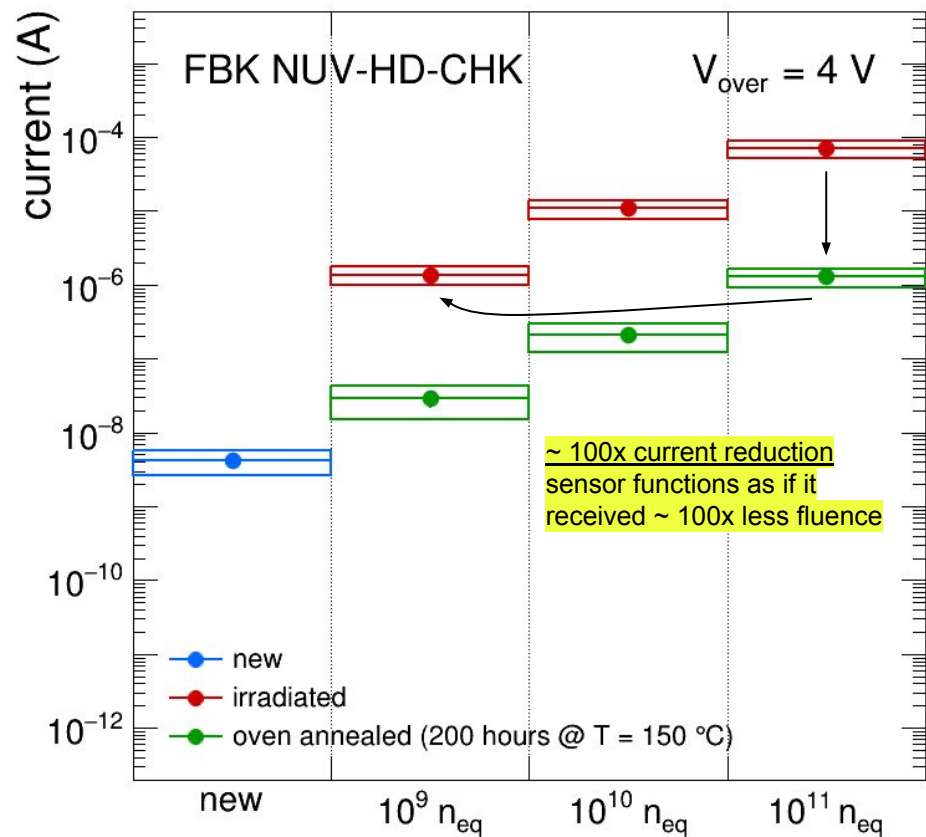


all results are reported at $T = -30 C$



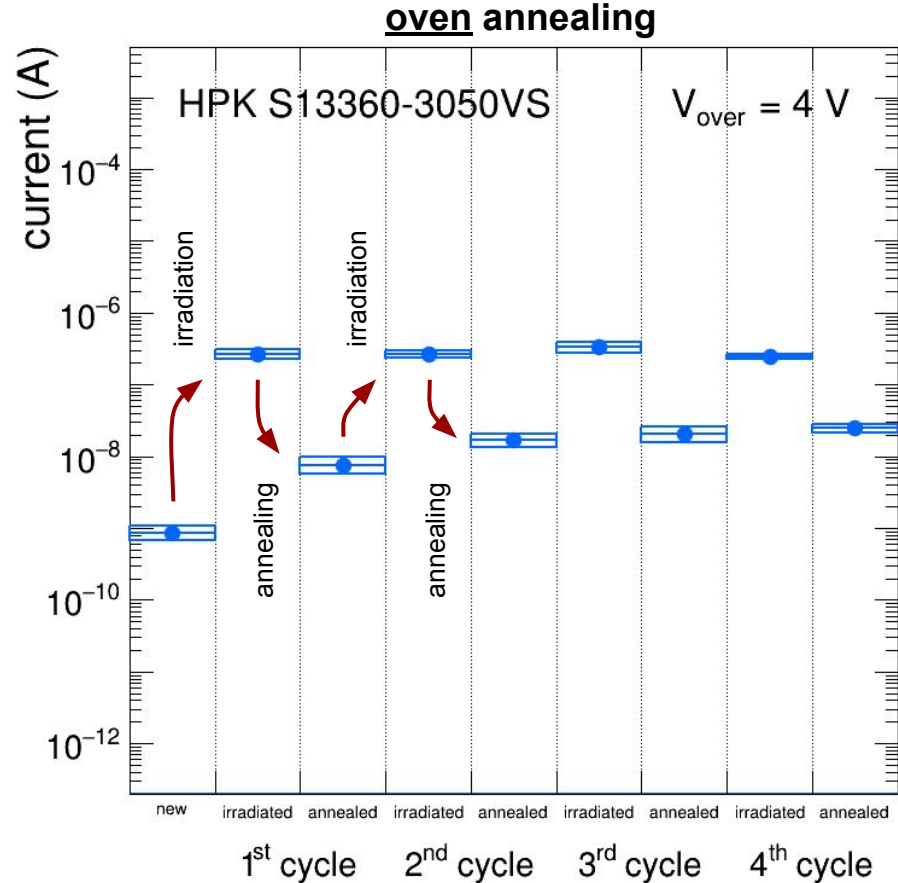
High-temperature annealing recovery

oven annealing
~ 1 week at 150 C



similar observation with various types of Hamamatsu sensors

Repeated irradiation-annealing cycles



test reproducibility of repeated irradiation-annealing cycles

simulate a realistic experimental situation

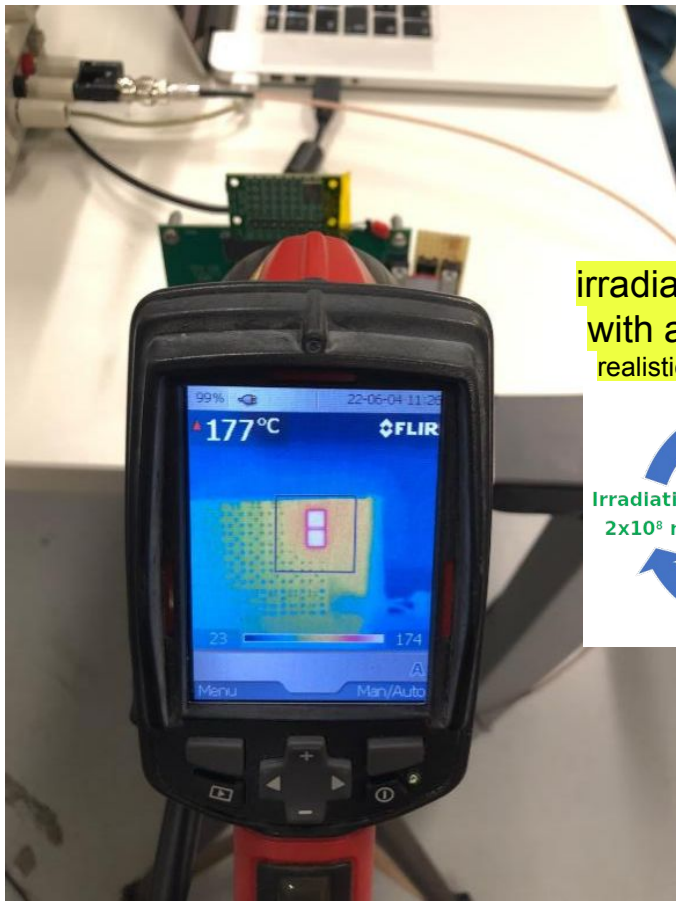
- consistent irradiation damage
 - DCR increases by $\sim 500 \text{ kHz}$ (@ $V_{\text{over}} = 4$)
 - after each shot of $10^9 n_{\text{eq}}$
- consistent residual damage
 - $\sim 15 \text{ kHz}$ (@ $V_{\text{over}} = 4$) of residual DCR
 - builds up after each irradiation-annealing

annealing cures same fraction of newly-produced damage

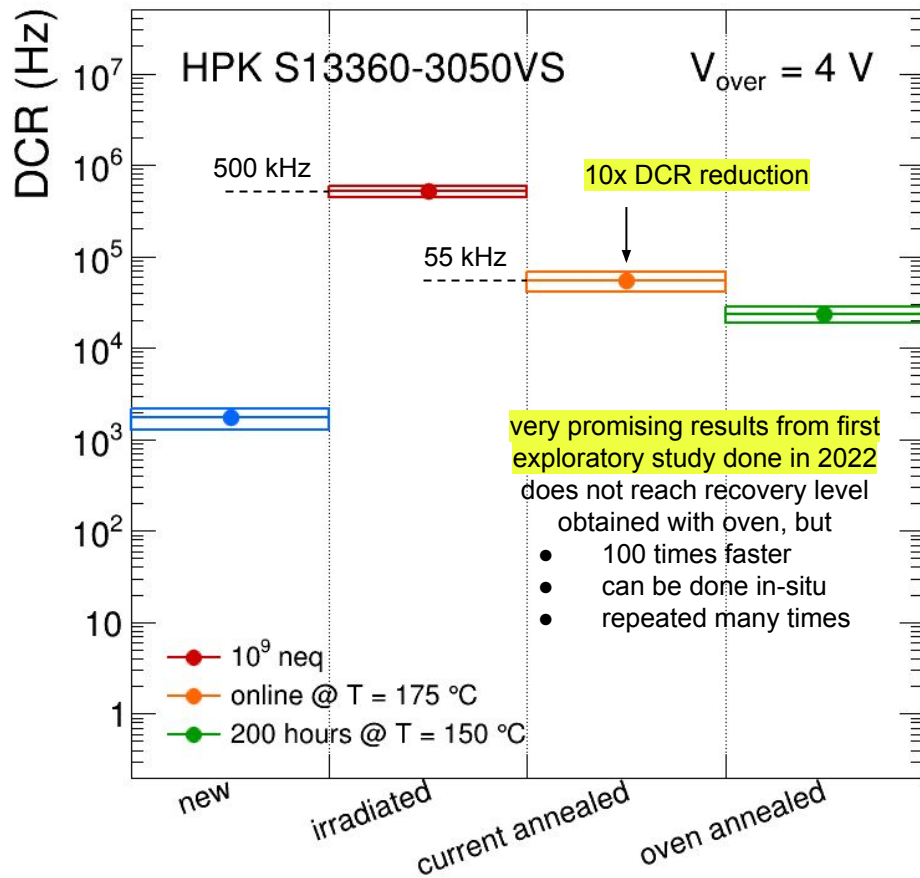
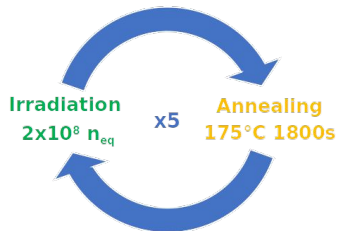
$\sim 97\%$ for HPK S13360-3050 sensors

“Online” self-induced annealing

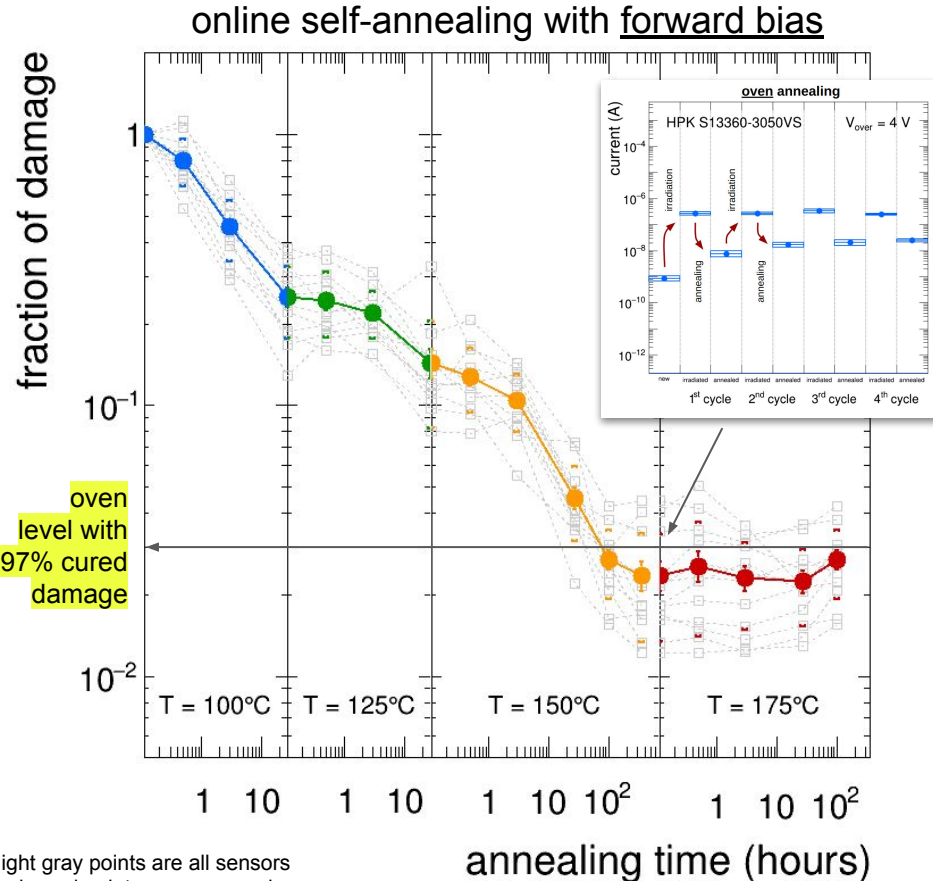
studies for “in-situ” SiPM recovery
 multiple cycles: 30 minutes at 175 C
 ~ 1 W power/sensor delivered with forward bias voltage



irradiation interleaved
 with annealing cycle
 realistic experimental case



Detailed studies of SiPM online self-annealing



**test on a large number SiPM sensors
how much damage is cured as a
function of temperature and time**

the same sensors have undergone self-annealing
increasing temperature steps
increasing integrated time steps

- started with T = 100 C annealing
 - performed 4 steps up to 30 hours integrated
- followed by T = 125, 150 and 175 C

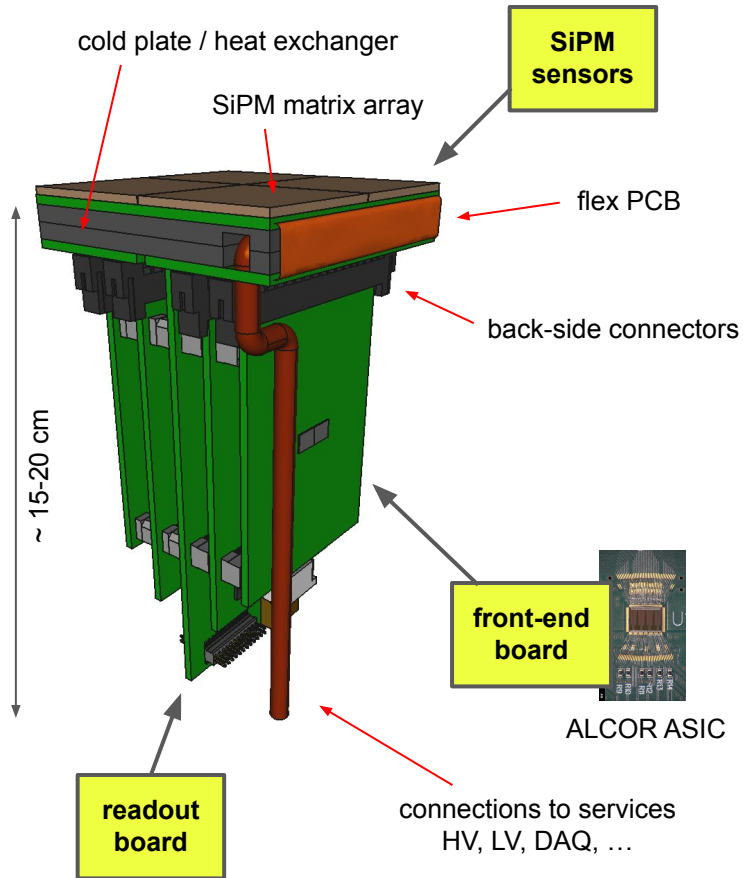
**fraction of residual damage
seems to saturate at 2-3%
after ~ 300 hours at T = 150 C**
continuing at higher T = 175 C seems
not to cure more than that

light gray points are all sensors
coloured points are averaged over sensors
coloured brackets is the RMS

detector integration
and electronics

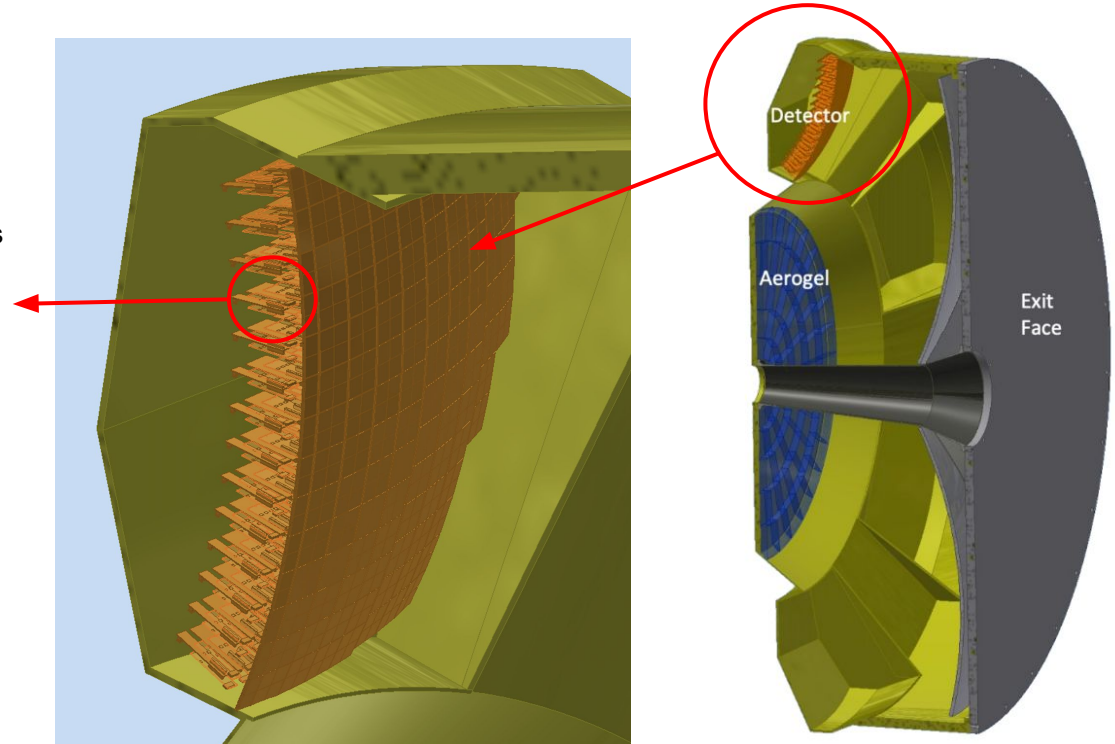
Photodetector unit

conceptual design of PDU layout

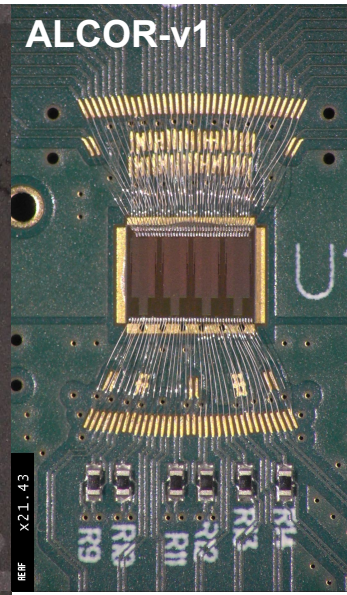
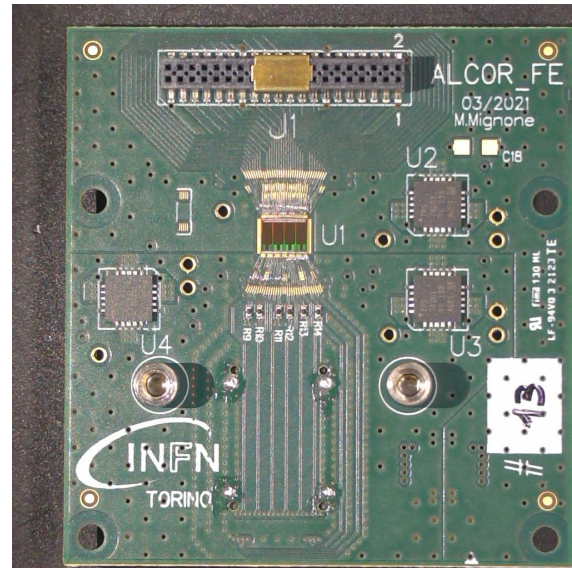


SiPM sensor matrices mounted on carrier PCB board

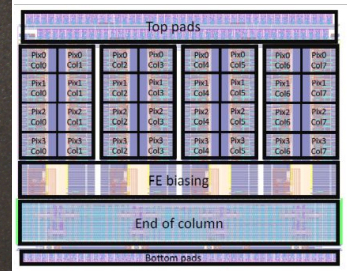
- 4x 64-channel SiPM array device (256 channels) for each unit
 - need modularity to realise curved readout surface
- 1248 photodetector units for full dRICH readout
 - 4992 SiPM matrix arrays (8x8)
 - 319488 readout channels



ALCOR ASIC: integrated front-end and TDC



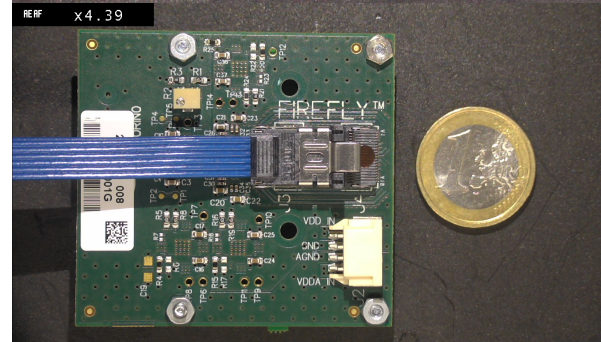
REF X2.1.43



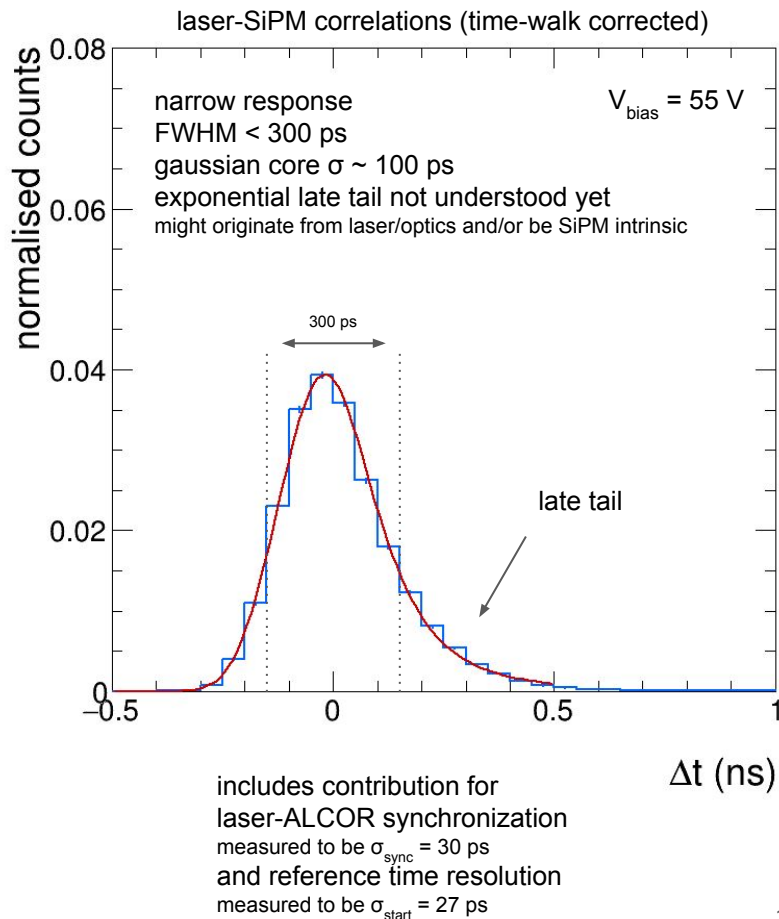
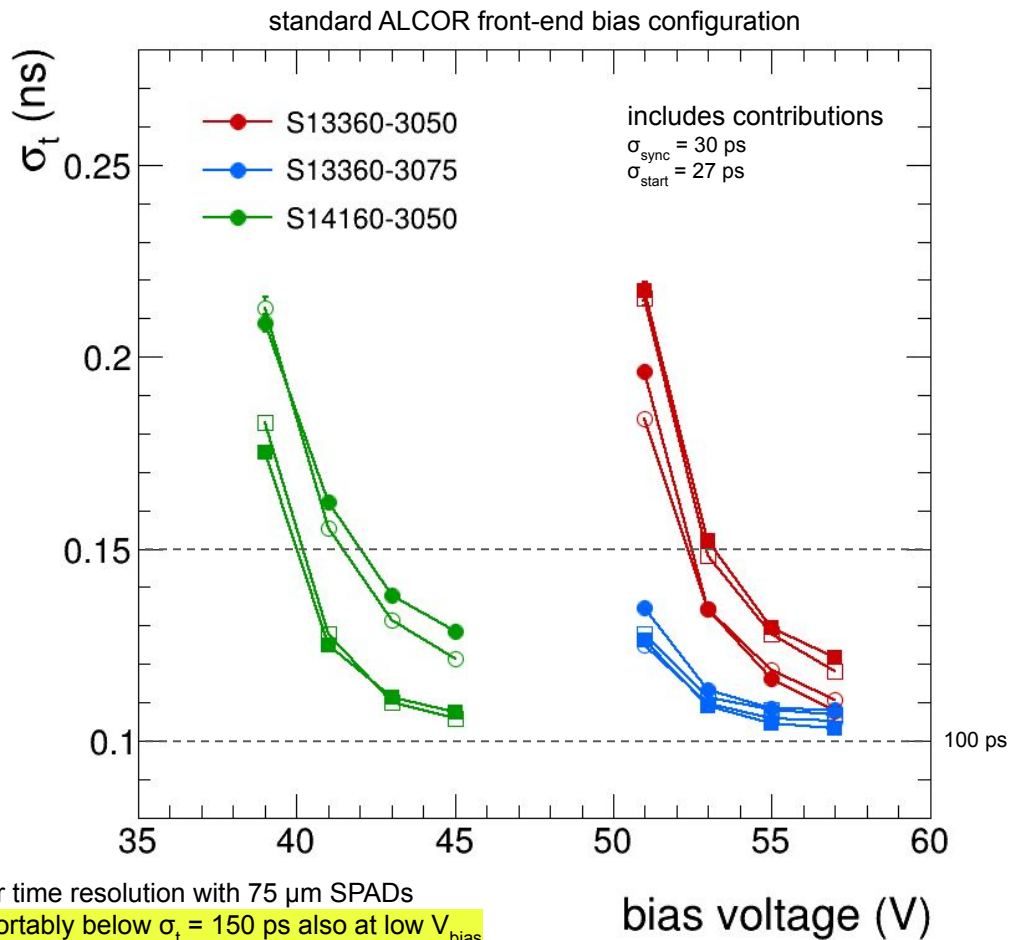
developed by INFN-TO

64-pixel matrix mixed-signal ASIC
 current versions (v1,v2,v2.1) have 32 channels, wirebonded
 final version will have 64 channels, BGA package, 394.08 MHz clock

- **the chip performs**
 - signal amplification
 - conditioning and event digitisation
- **each pixel features**
 - 2 leading-edge discriminators
 - 4 TDCs based on analogue interpolation
 - 20 or 40 ps LSB (@ 394 MHz)
 - digital shutter to enable TDC digitisation
 - suppress out-of-gate DCR hits
 - 1-2 ns timing window
 - programmable delay, sub ns accuracy
- **single-photon time-tagging mode**
 - continuous readout
 - also with Time-Over-Threshold
- **fully digital output**
 - 8 LVDS TX data links

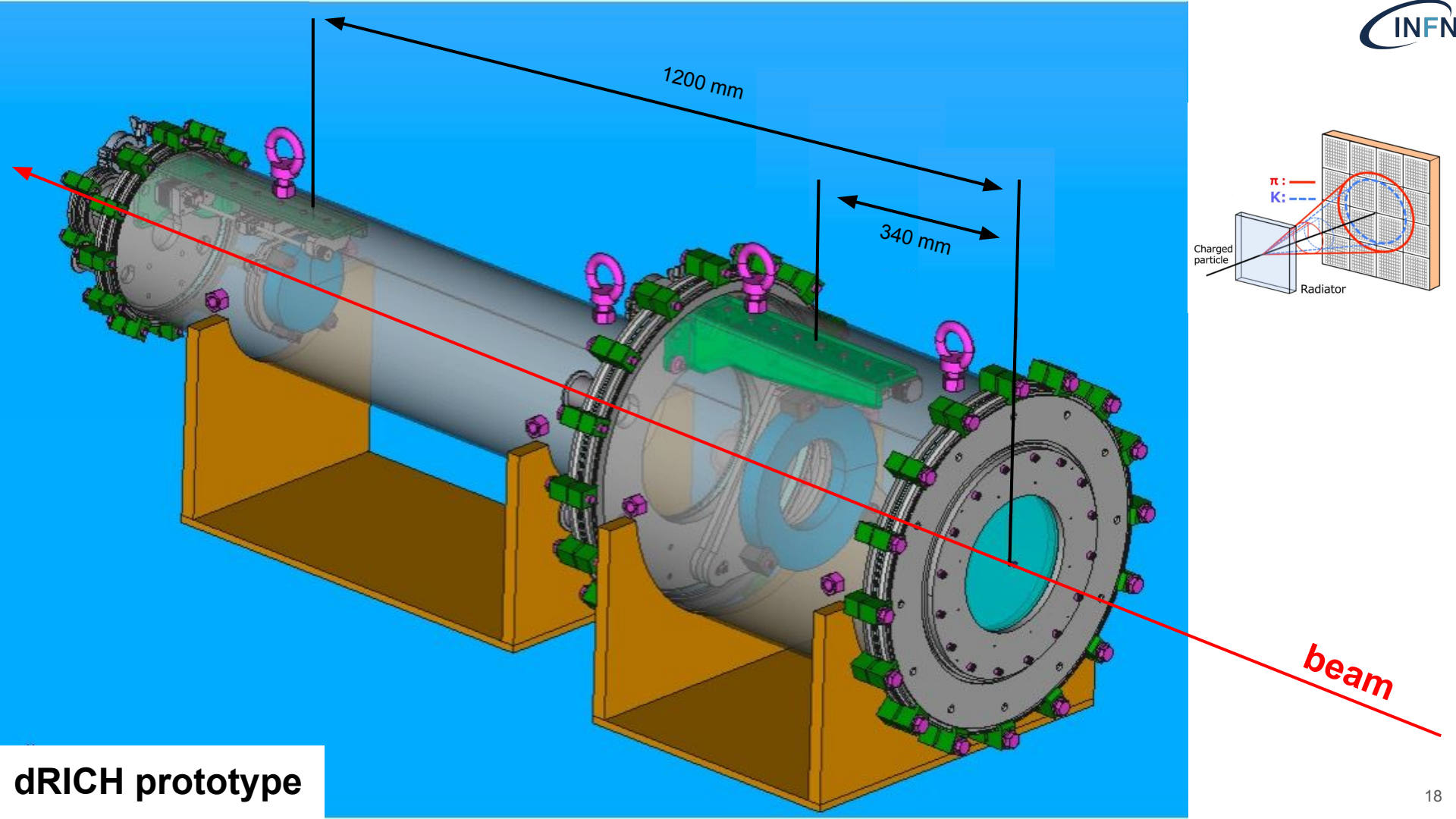


Timing performance measurements with ALCOR



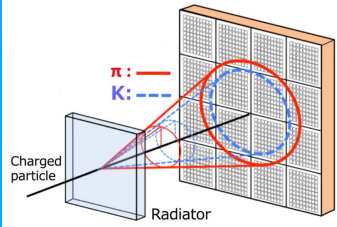
better time resolution with 75 μm SPADs
 comfortably below $\sigma_t = 150 \text{ ps}$ also at low V_{bias}

detector prototype
and beam tests



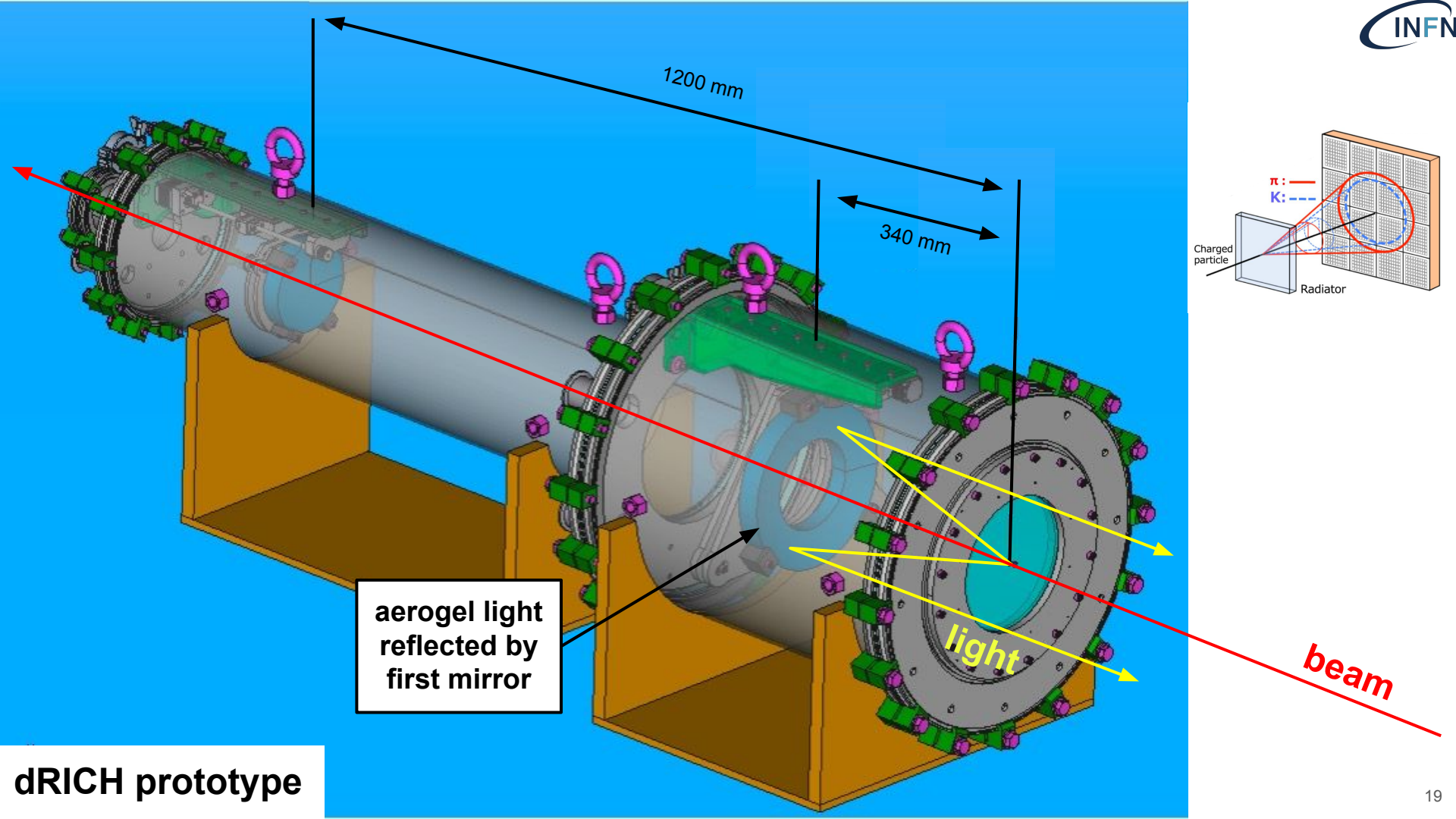
1200 mm

340 mm



beam

dRICH prototype



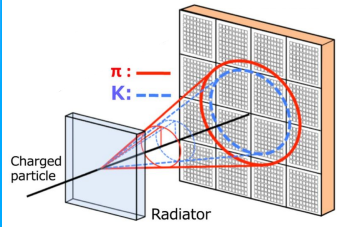
aerogel light reflected by first mirror

light

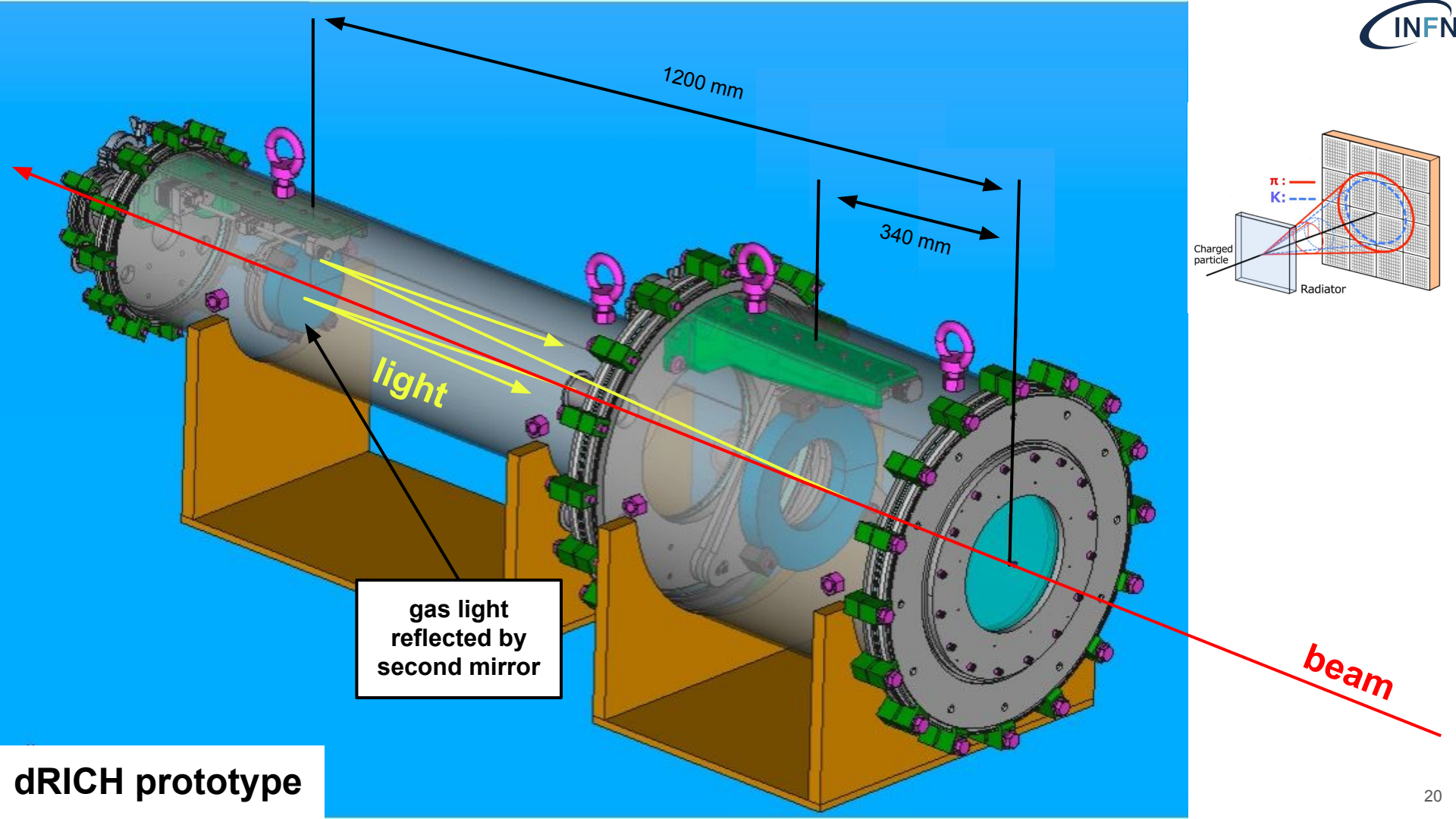
beam

1200 mm

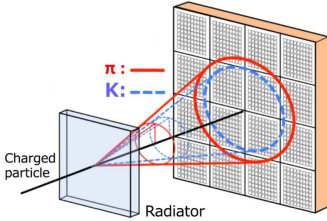
340 mm



dRICH prototype

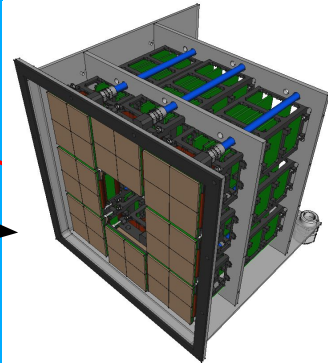
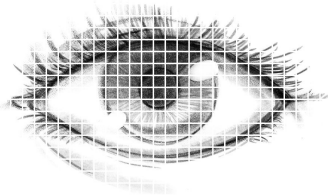
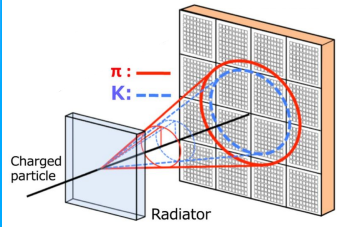
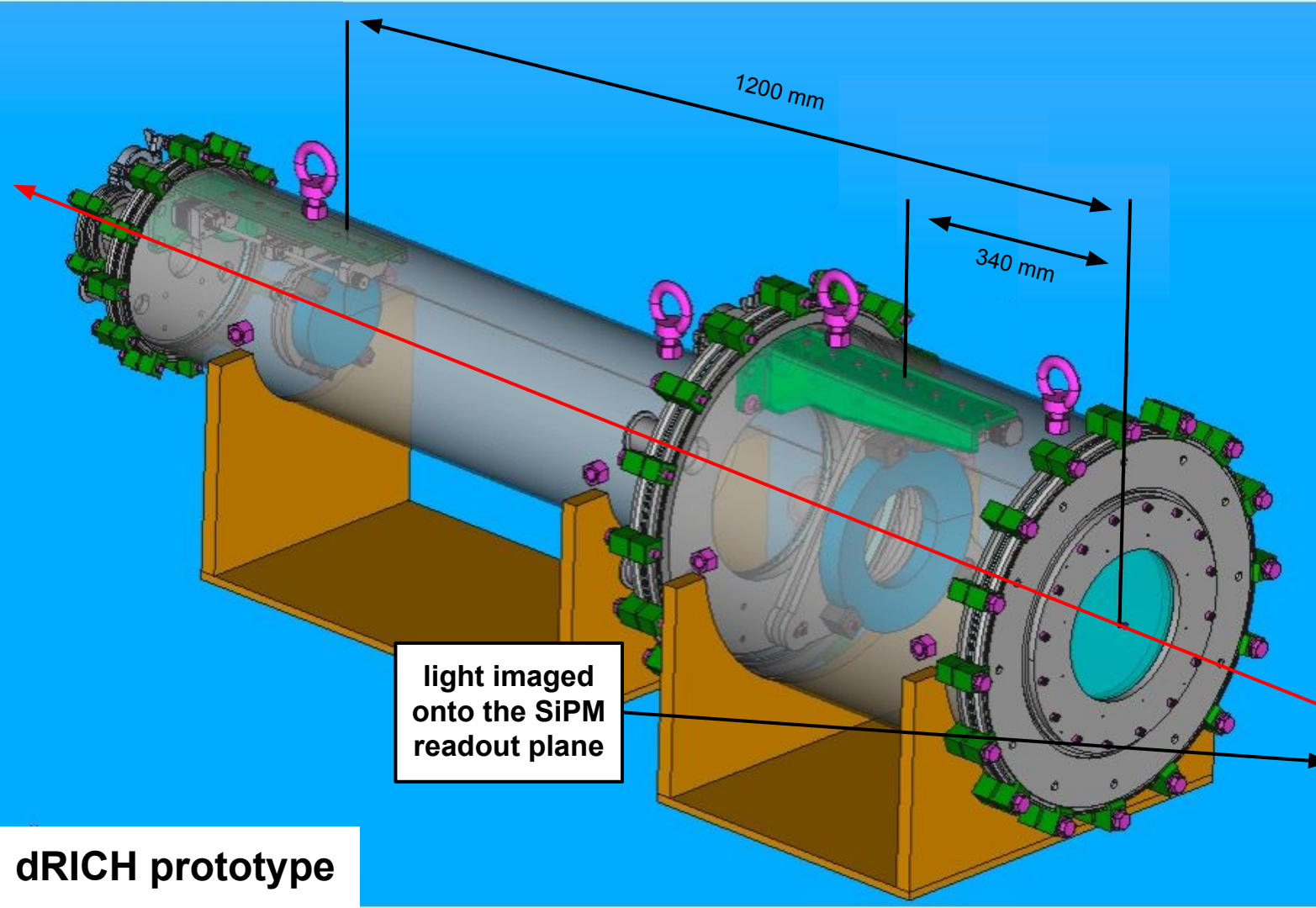


gas light
reflected by
second mirror



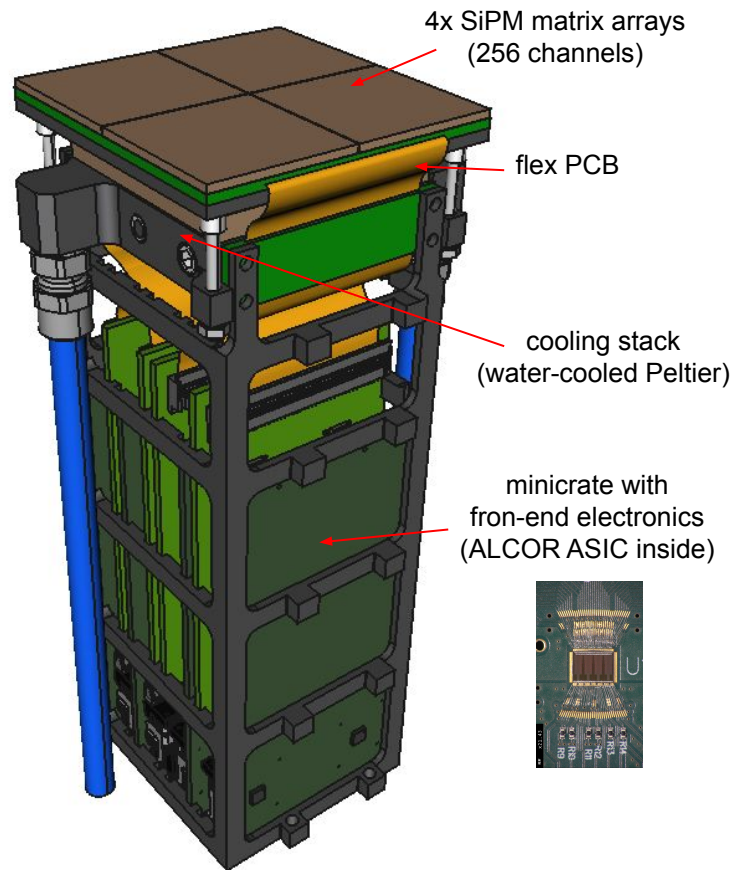
beam

dRICH prototype

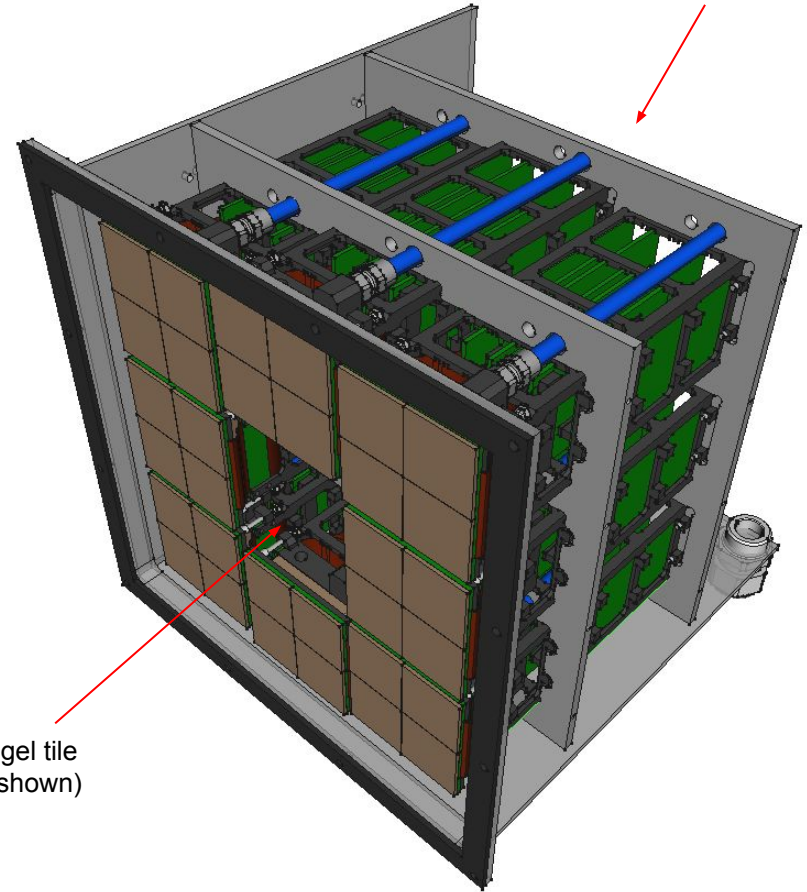


dRICH prototype

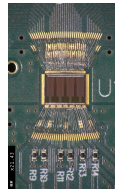
EIC ePIC-dRICH SiPM photodetector prototype



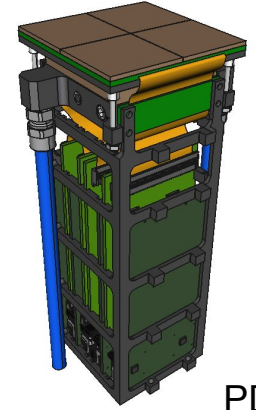
PhotoDetector Unit (PDU)



Readout Box

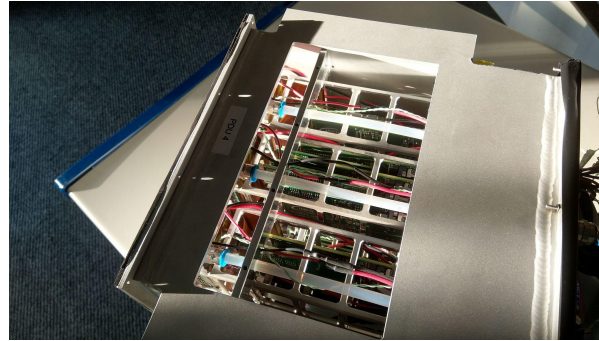


dRICH SiPM photodetector prototype in 2023



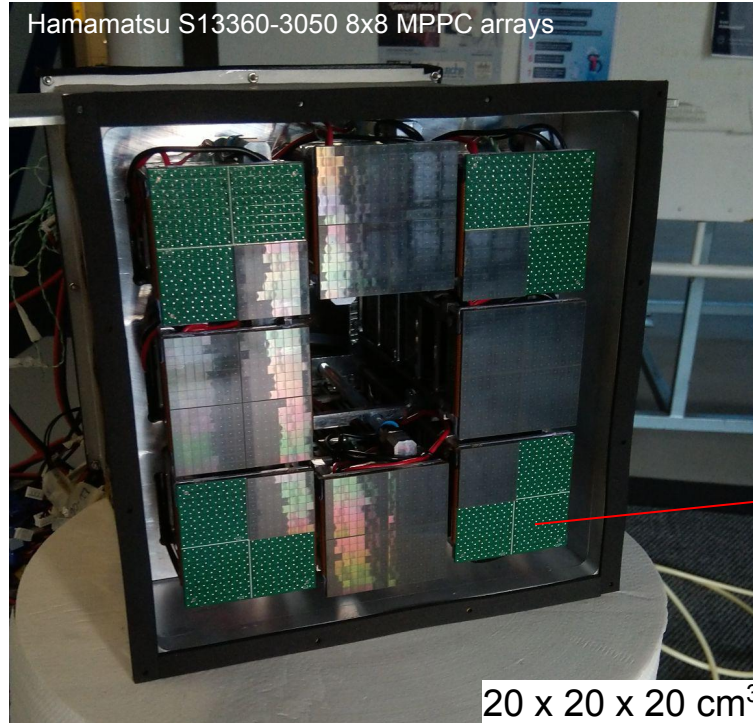
PDU

(top)

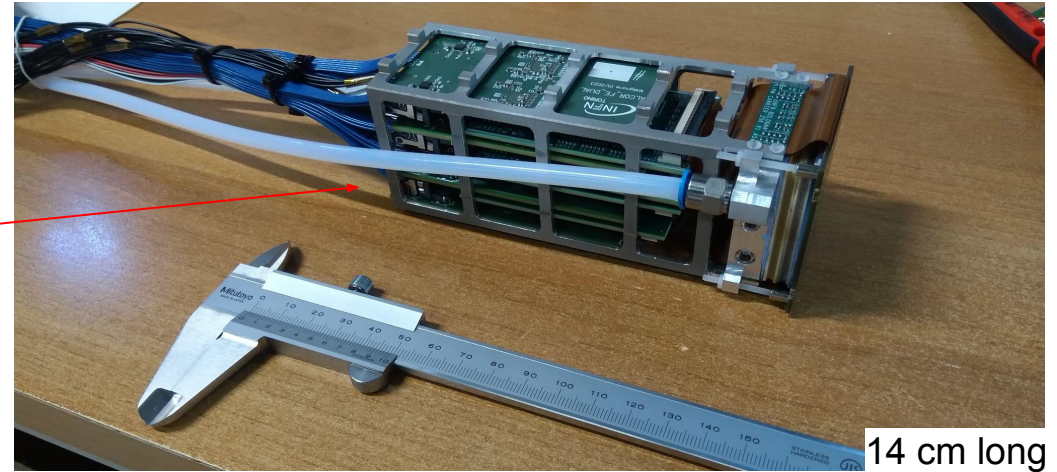


Readout Box (front)

Hamamatsu S13360-3050 8x8 MPPC arrays



20 x 20 x 20 cm³



14 cm long

partially-equipped, 1280-channels SiPM readout surface with cooling and TDC electronics

DAQ and DCS computers

auxiliary control electronics crates

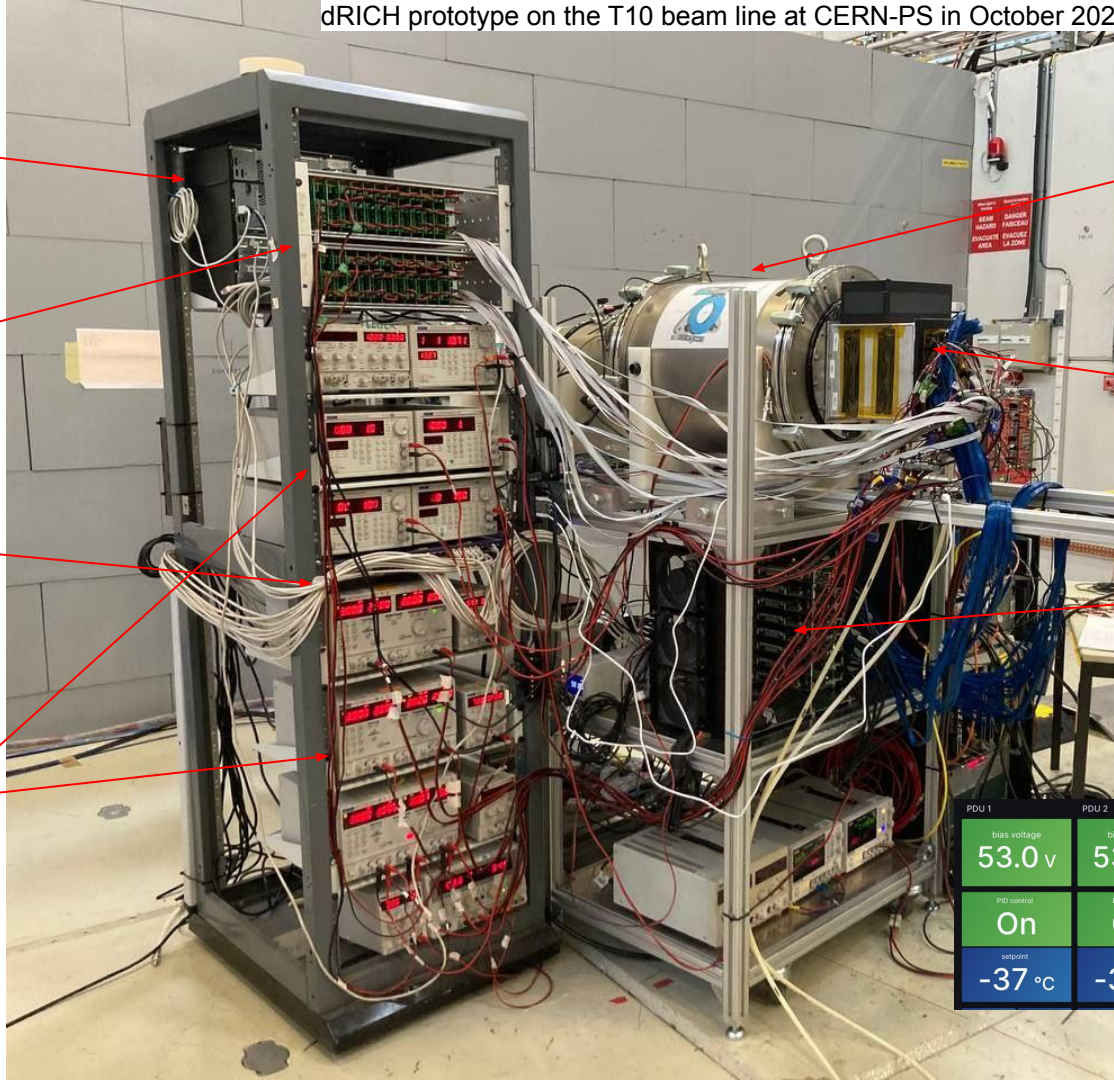
gigabit ETH switch for DAQ and DCS

low voltage and high voltage power supplies

dRICH prototype

SiPM photodetector readout box

DAQ FPGAs and clock distribution

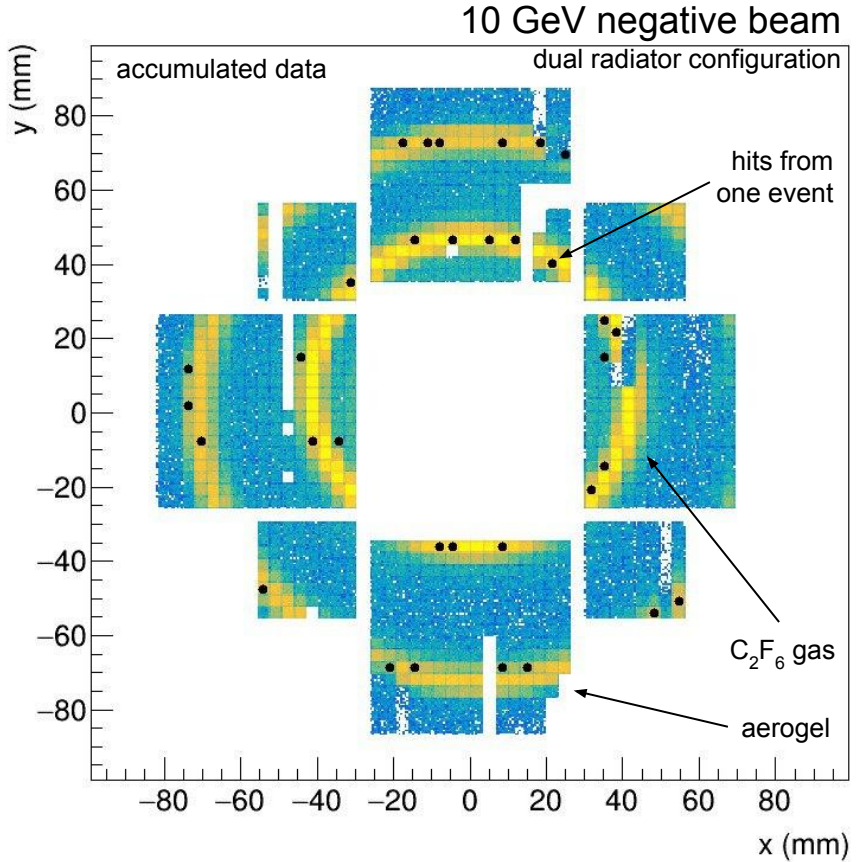
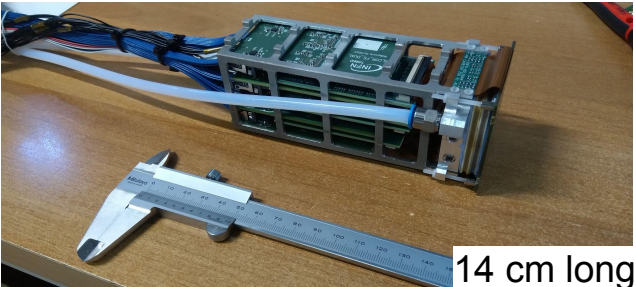
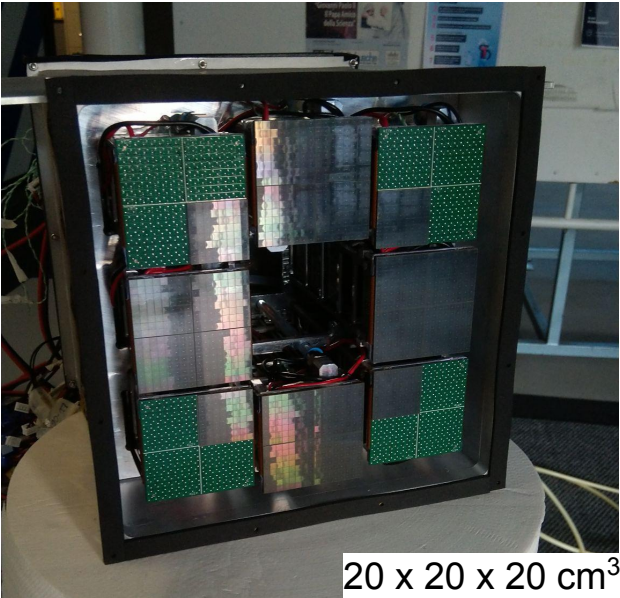
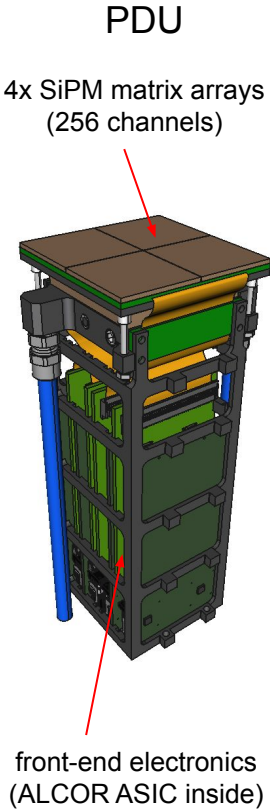


PDU 1	PDU 2	PDU 3	PDU 4
bias voltage 53.0 v	bias voltage 53.0 v	bias voltage 53.0 v	bias voltage 53.0 v
PID control On	PID control On	PID control On	PID control On
setpoint -37 °C	setpoint -37 °C	setpoint -37 °C	setpoint -35 °C

SiPM at low temperature

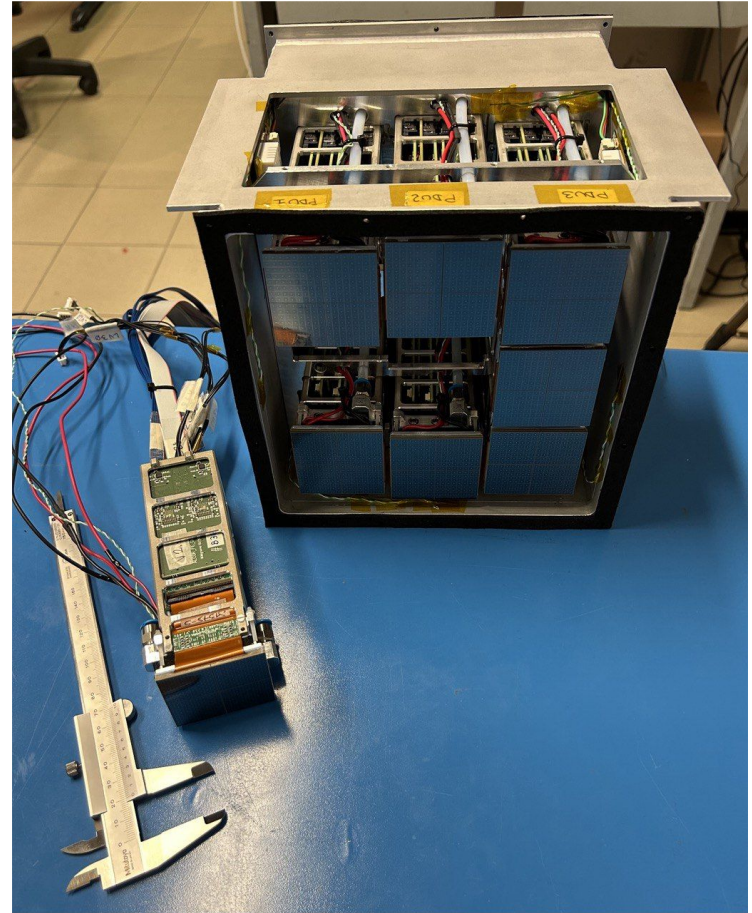
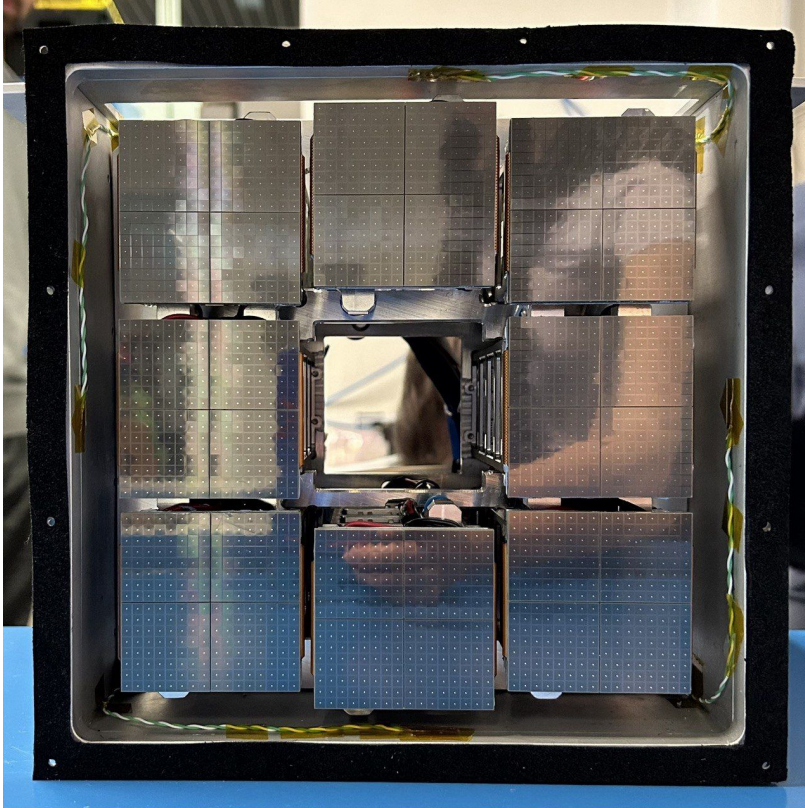
2023 test beam at CERN-PS

successful beam test with prototype SiPM photodetector units (CERN-PS, ended on 18th October)



Upgraded in 2024 with 2k channels

Hamamatsu S13360-3050/3075 8x8 MPPC arrays



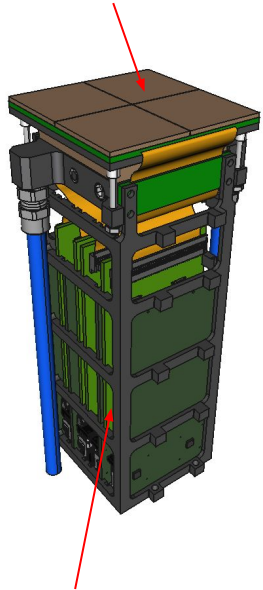
fully-equipped, **2048-channels** SiPM readout surface with cooling and TDC electronics

2024 test beam at CERN-PS

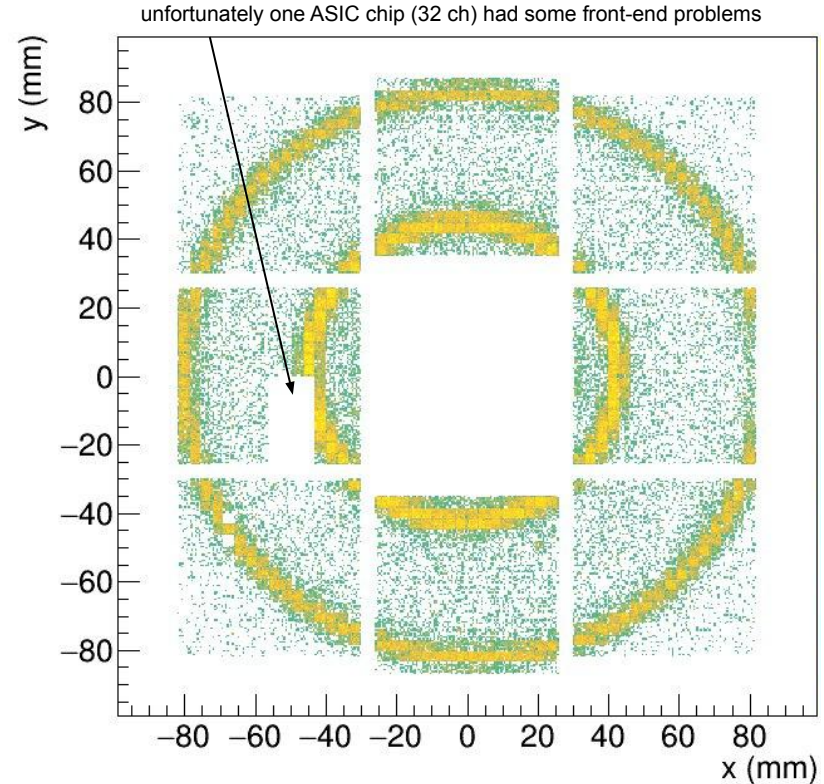
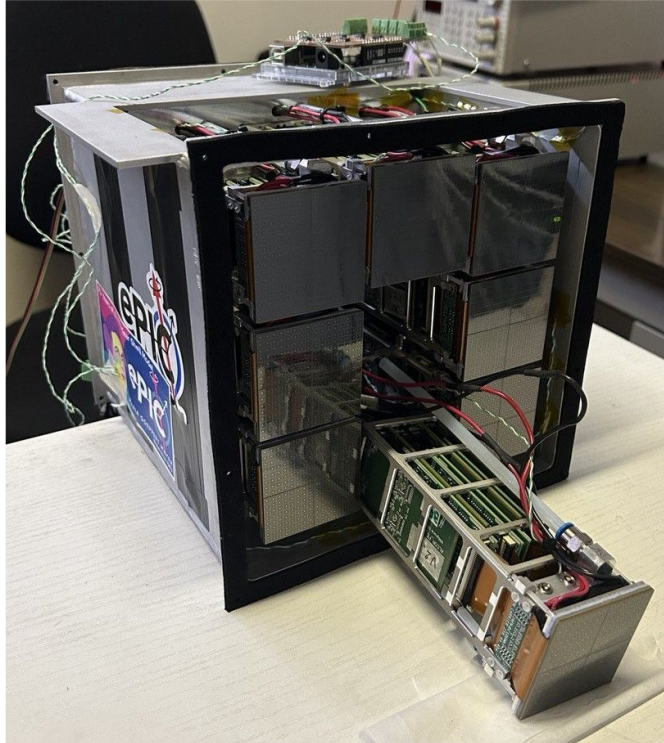
another successful beam test with prototype SiPM photodetector units (CERN-PS, ended on 5th June)

PDU

4x SiPM matrix arrays
(256 channels)



front-end electronics
(ALCOR ASIC inside)

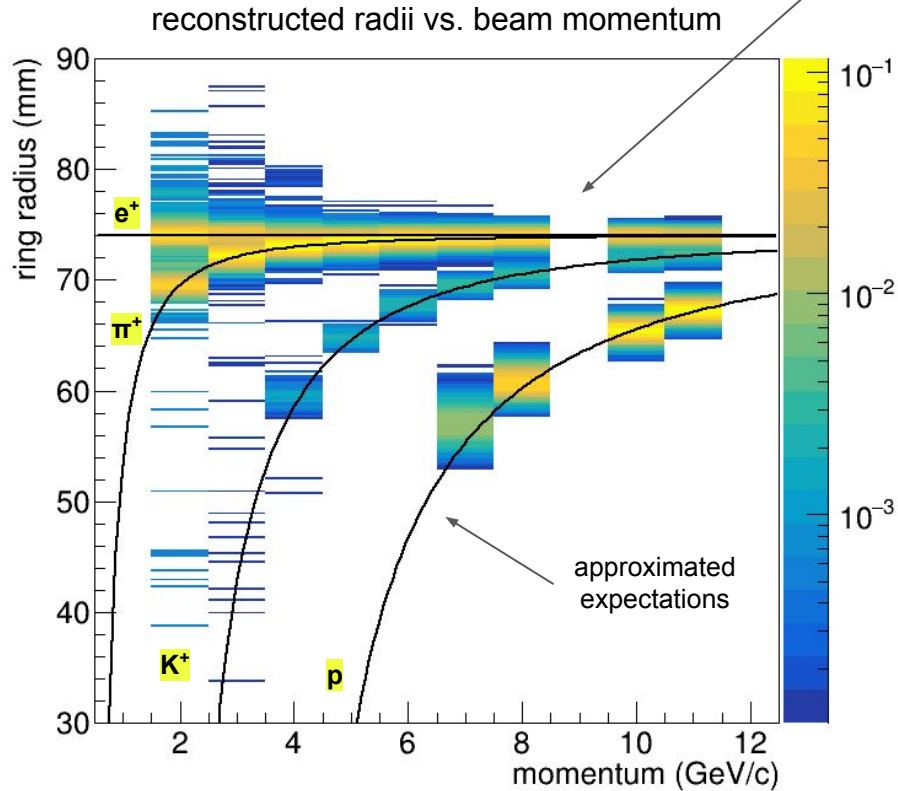


all the rest was rather full of photons
> 2000 SiPMs with TDC readout at work

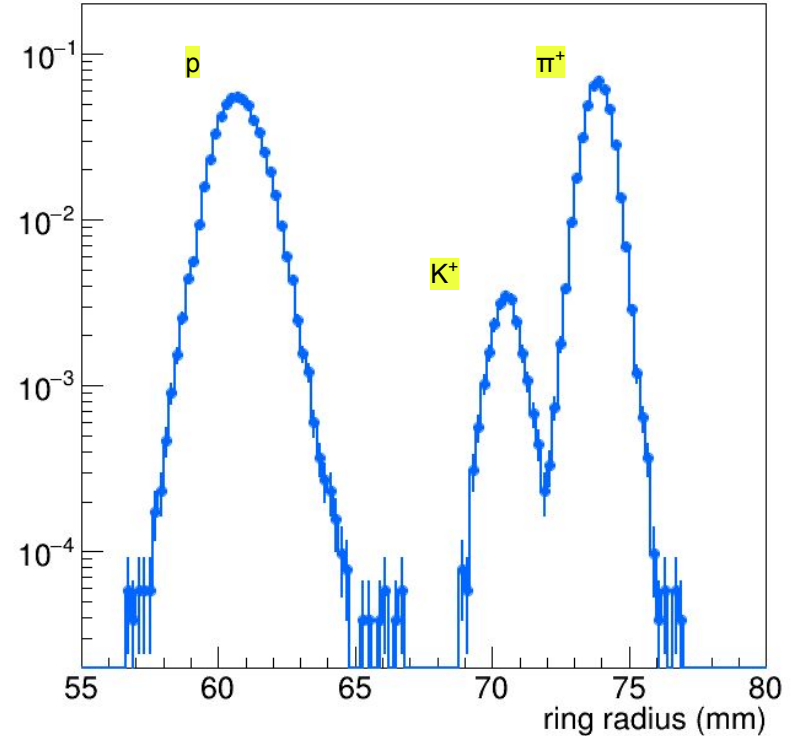
Beam momentum scan

positive particles, aerogel only

something went wrong with the beam configuration for 9 GeV
(that's a pity, data seems not good)



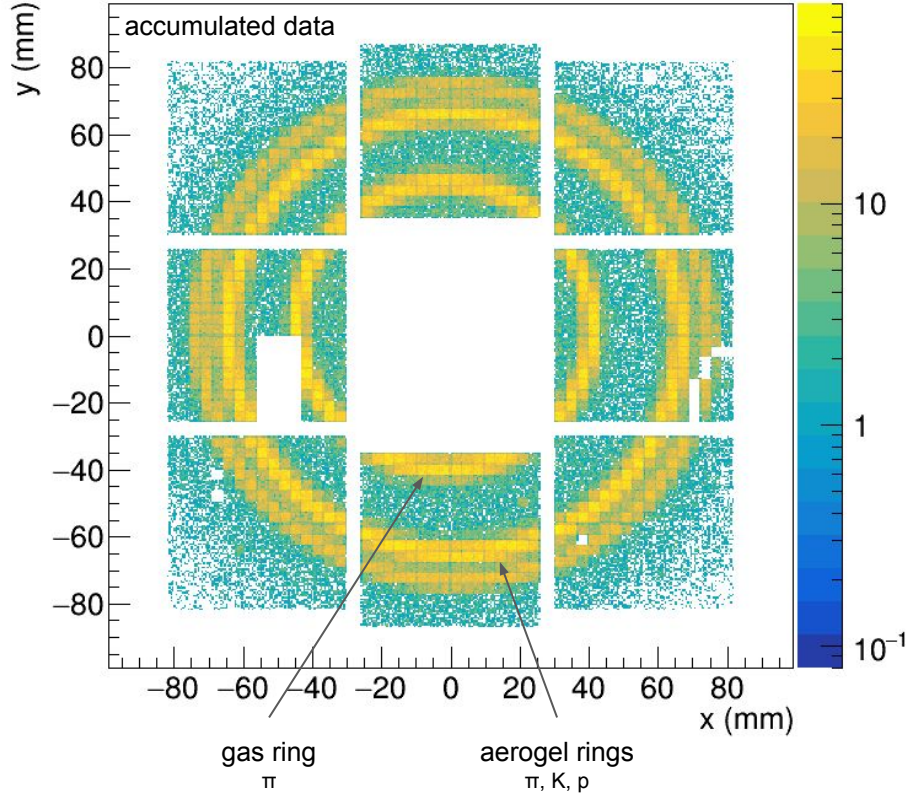
reconstructed ring radius at 8 GeV/c beam momentum



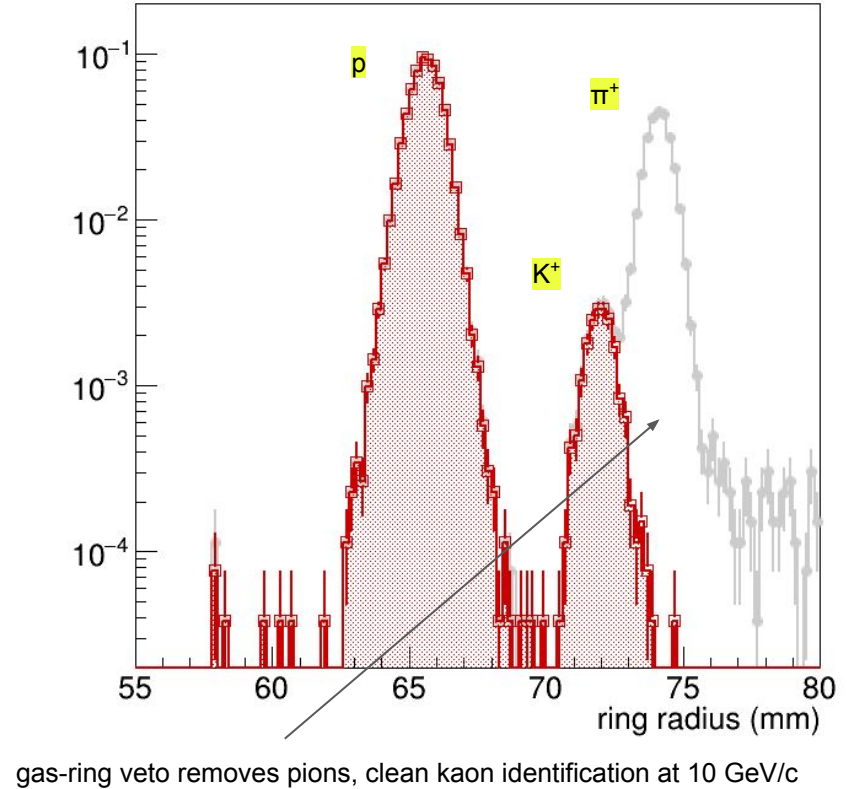
Interplay between aerogel and gas radiators

gas ring tags pions, at 10 GeV/c kaons and protons are below C_2F_6 gas threshold

10 GeV/c positive beam with no selection applied



reconstructed ring radius at 10 GeV/c with gas veto

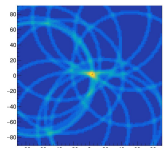


Summary

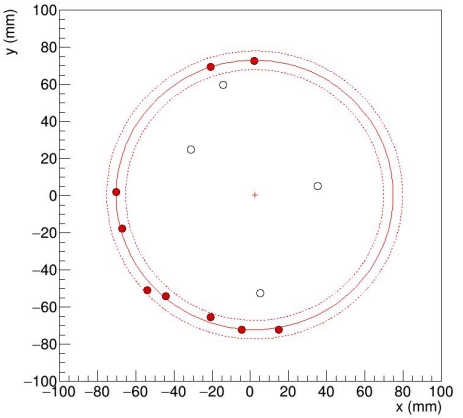
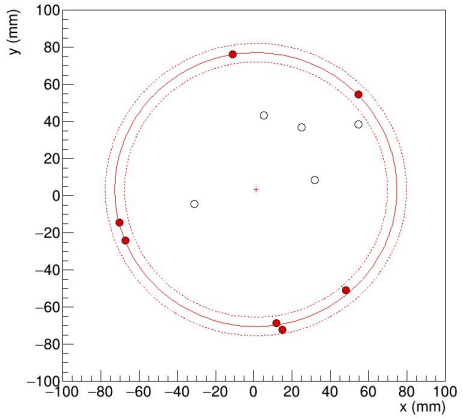
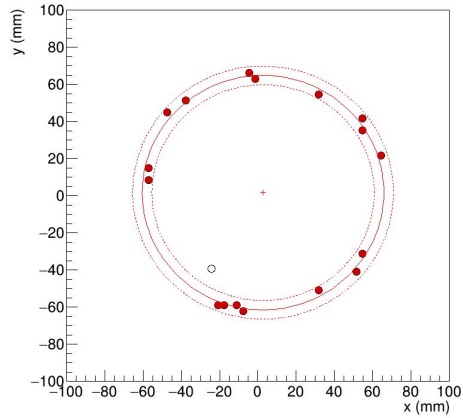
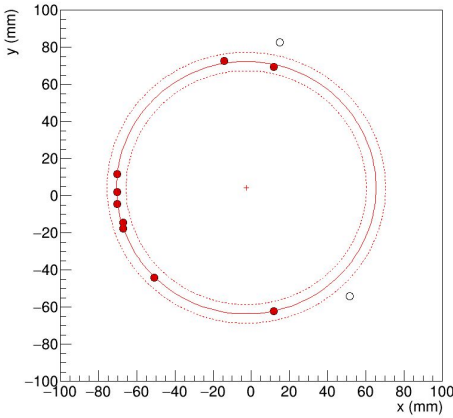
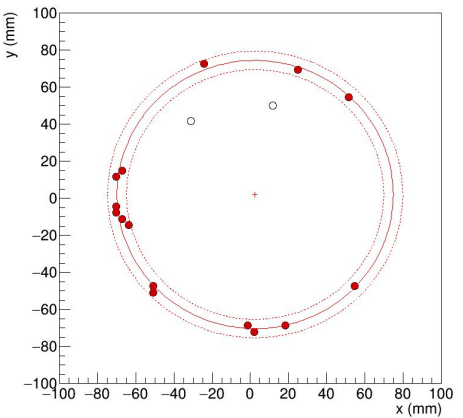
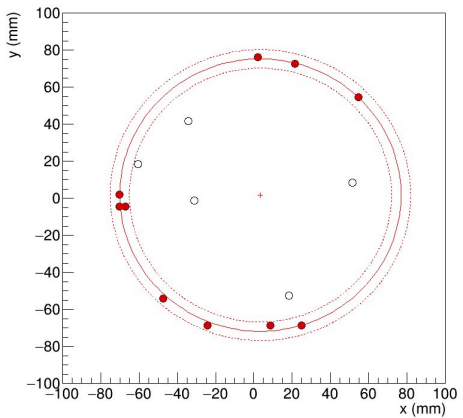
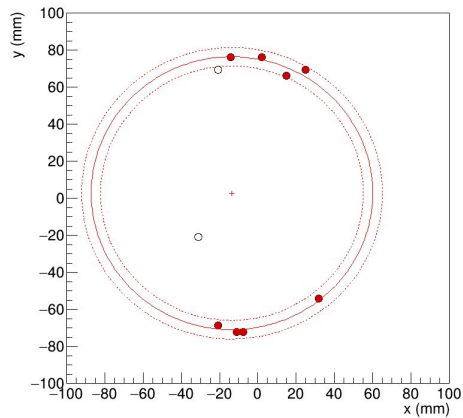
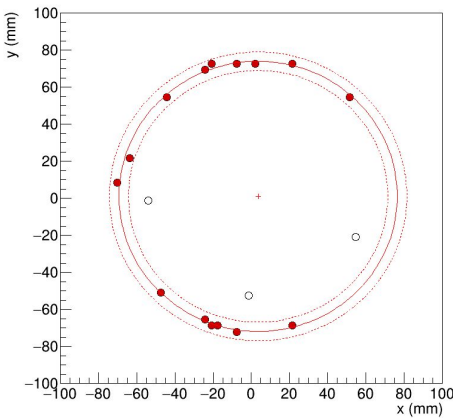
- **dRICH SiPM option fulfills dRICH requirements**
 - magnetic field limitations
 - excellent timing and efficiency
- **technical solutions to mitigate radiation damage**
 - low temperature operation
 - online “in-situ” self-annealing
 - extend lifetime of good detector performance for Physics
 - present solutions can be optimised/improved to extend it further
- **SiPM readout with full electronics chain**
 - based on ALCOR ASIC
 - successful beam tests at CERN-PS in 2022, 2023 and 2024
 - overall 1-pe time resolution approaching 100 ps
 - ring-imaging, particle-identification and more
 - beam test data-analysis ongoing
- **clear path for optimisation towards TDR and beyond**
 - refinements, engineering and SiPM sensor selection in 2025 and 2026
 - SiPM readout mass production in 2027-2029
 - dRICH detector installation in the ePIC experiment in 2030

2023 test beam data analysis ongoing

event-by-event ring reconstruction: Hough Transform Method



10 GeV negative beam
only aerogel radiator



2023 test beam data analysis ongoing



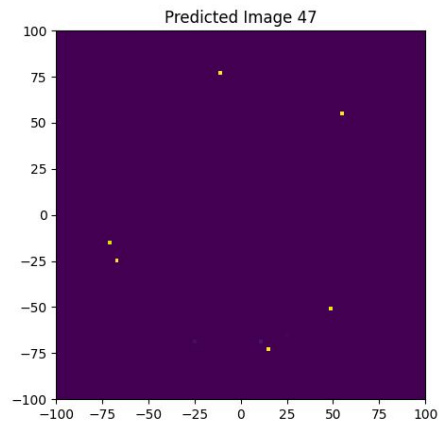
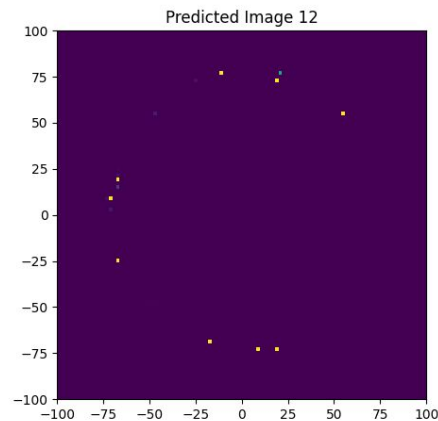
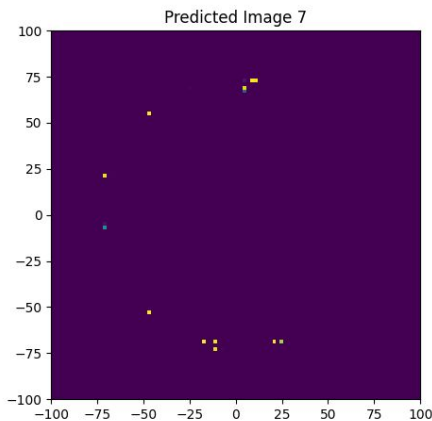
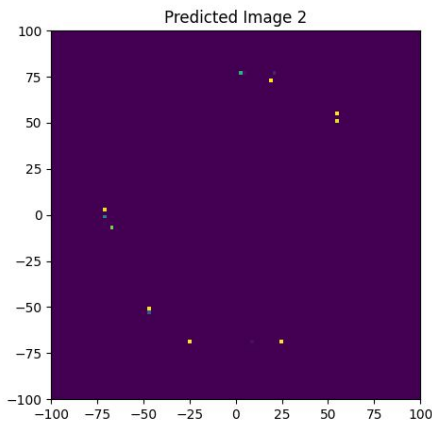
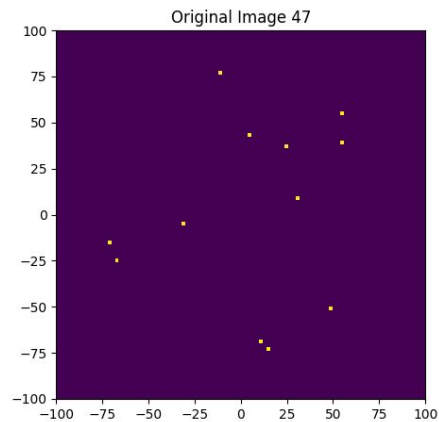
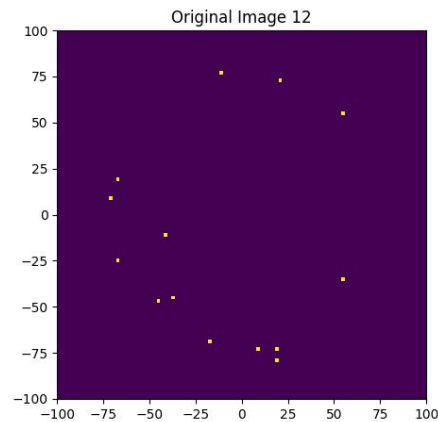
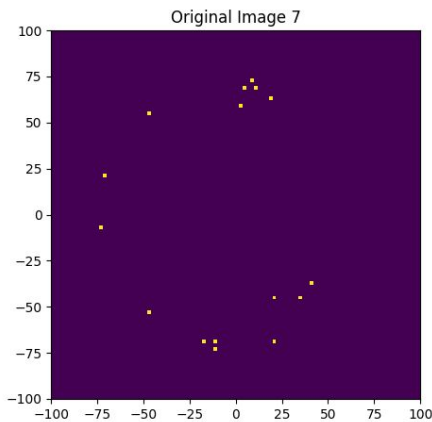
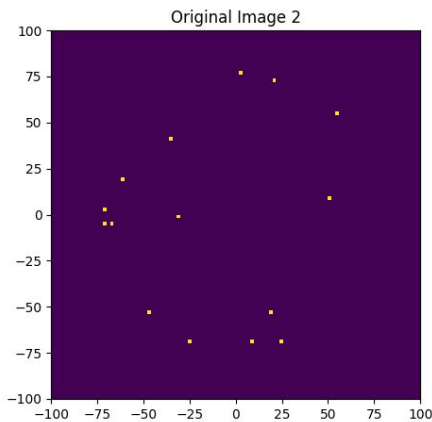
event-by-event ring reconstruction: Machine Learning

10 GeV negative beam
only aerogel radiator

input image



ML prediction



2023 test beam data analysis ongoing

event-by-event ring reconstruction: Machine Learning

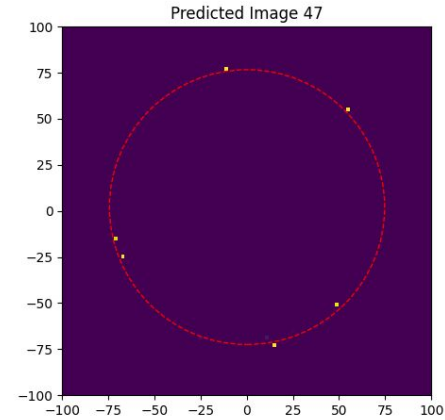
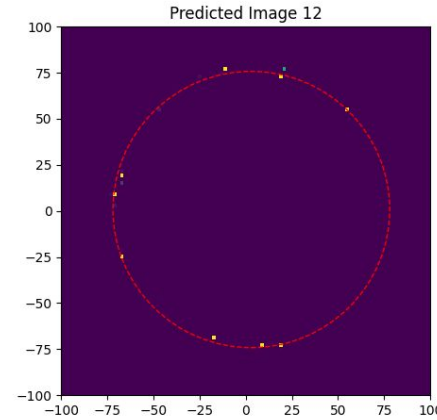
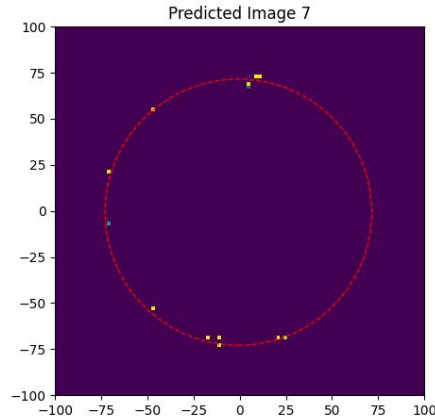
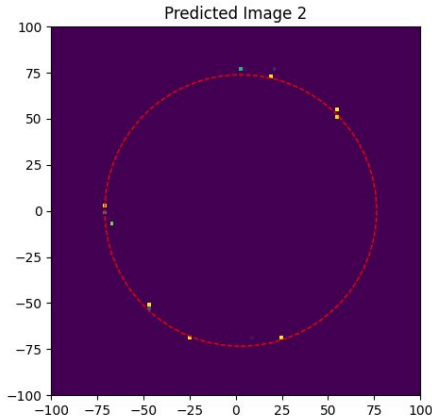
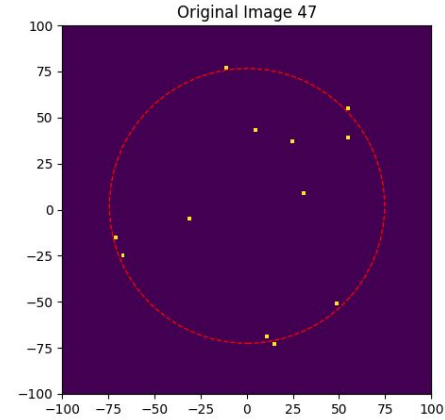
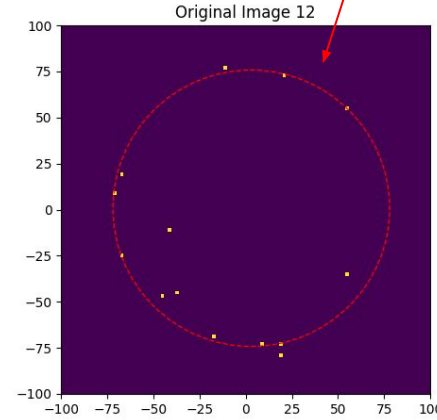
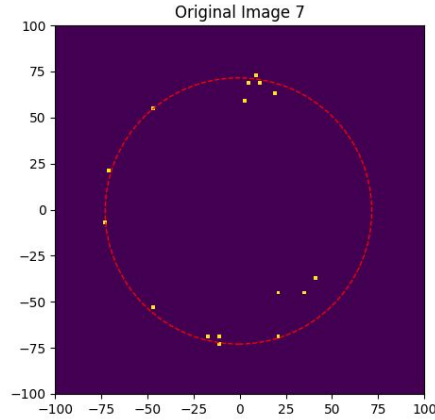
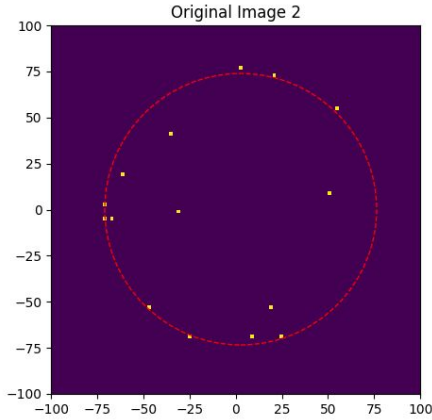
circle fit on ML prediction

10 GeV negative beam
only aerogel radiator

input image



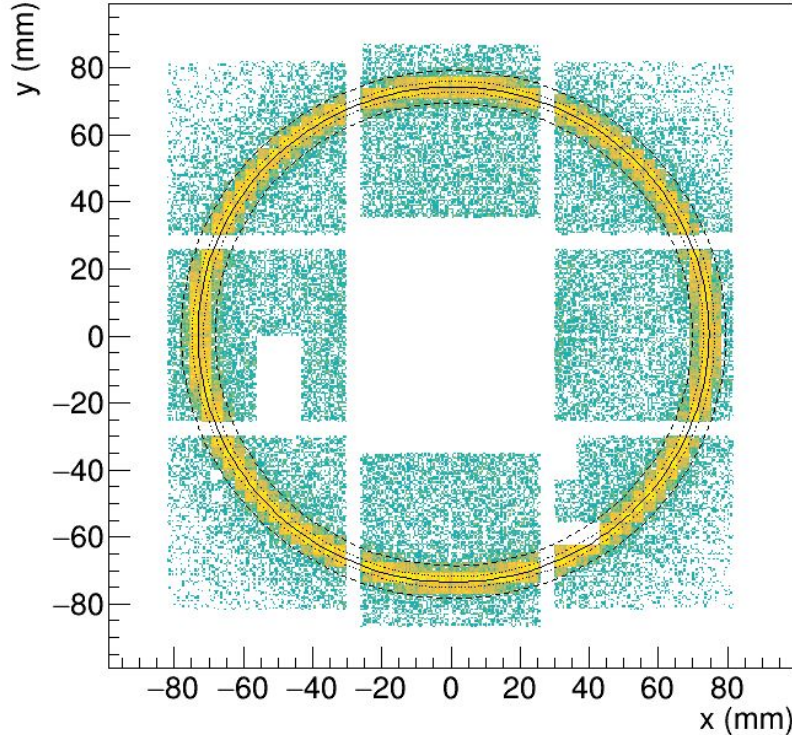
ML prediction



Number of photoelectrons

is large as expected

11.5 GeV/c negative beam, $n = 1.02$ aerogel (accumulated events)



$$X_0 = 0.75 \pm 0.01 \text{ mm}$$

$$Y_0 = 0.45 \pm 0.01 \text{ mm}$$

$$R = 73.87 \pm 0.00 \text{ mm}$$

$$\sigma_R = 1.63 \pm 0.00 \text{ mm}$$

average number of signal photons for 100% acceptance includes SiPM efficiency

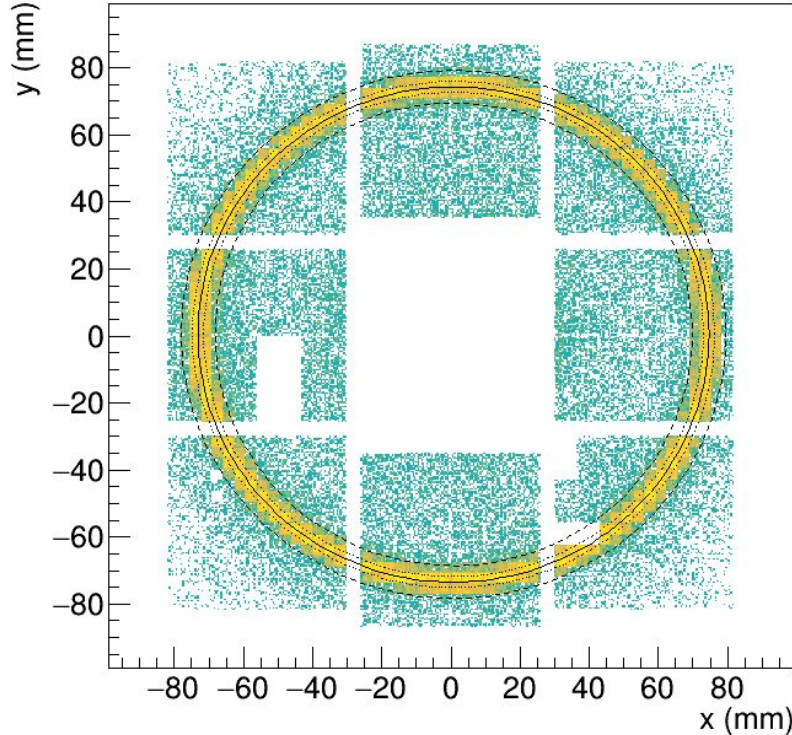
$$N_{\text{sig}} = 29.13 \pm 0.07$$

$$N_{\text{bkg}} = 8.47 \pm 0.05$$

Number of photoelectrons

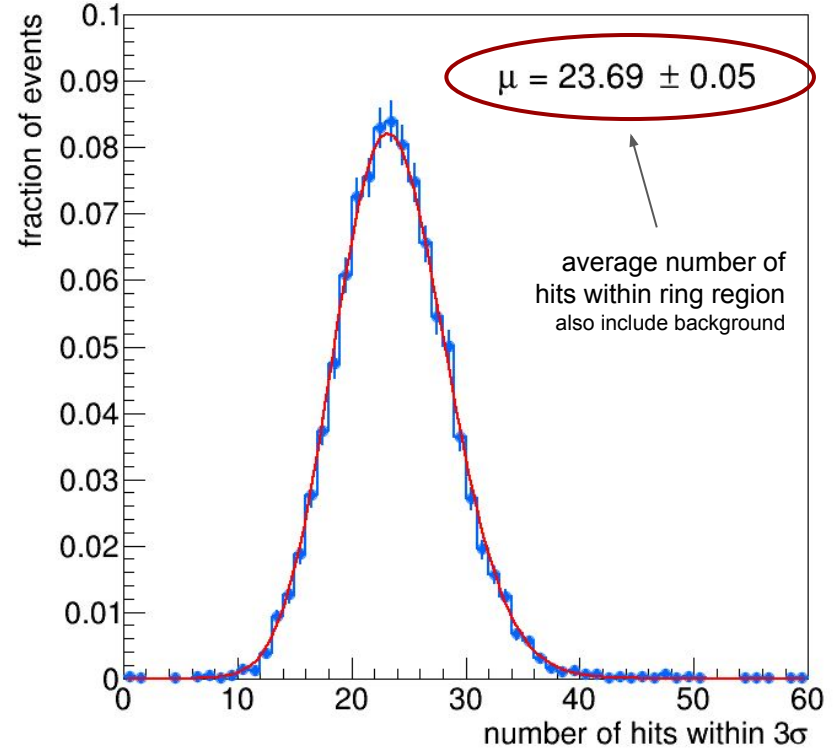
large as expected

11.5 GeV/c negative beam, $n = 1.02$ aerogel (accumulated events)



2D fit to accumulated data with realistic model (ring + background)

event-by-event distribution of hits in the ring



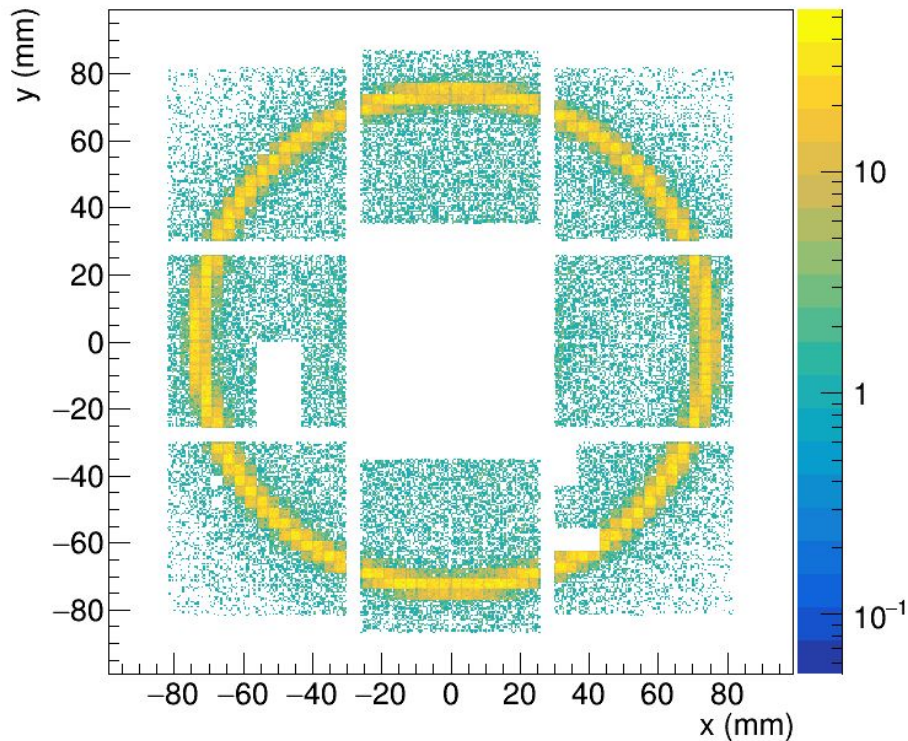
Poisson fit to data, average number of hits is large

Background studies

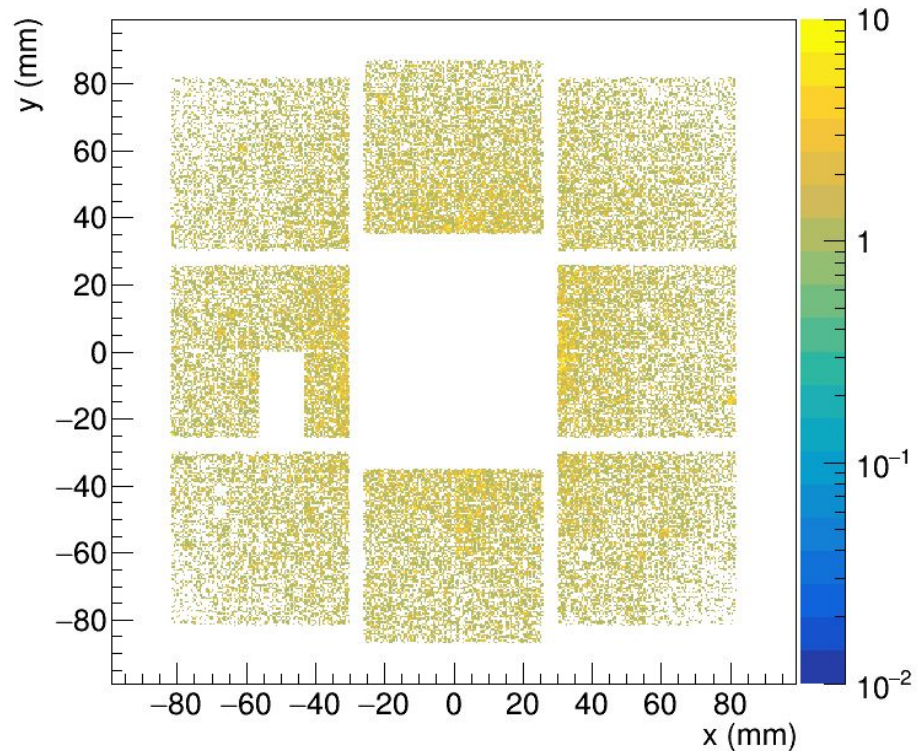
data taken without aerogel radiator



with two $n = 1.02$ aerogel tiles (accumulated events)



without aerogel (accumulated events)



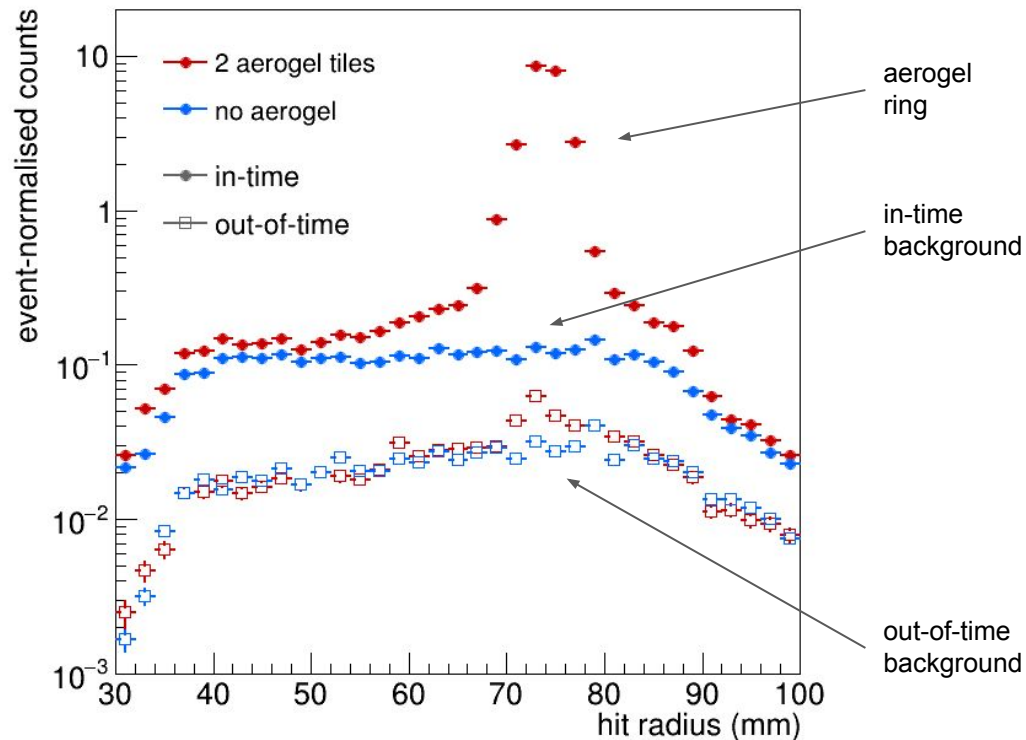
with timing cuts applied, large background as seen in past years

removed the aerogel tile, background remains

Background studies

basically all the background remains after removing aerogel, not from DCR

distribution hit radii with and without aerogel

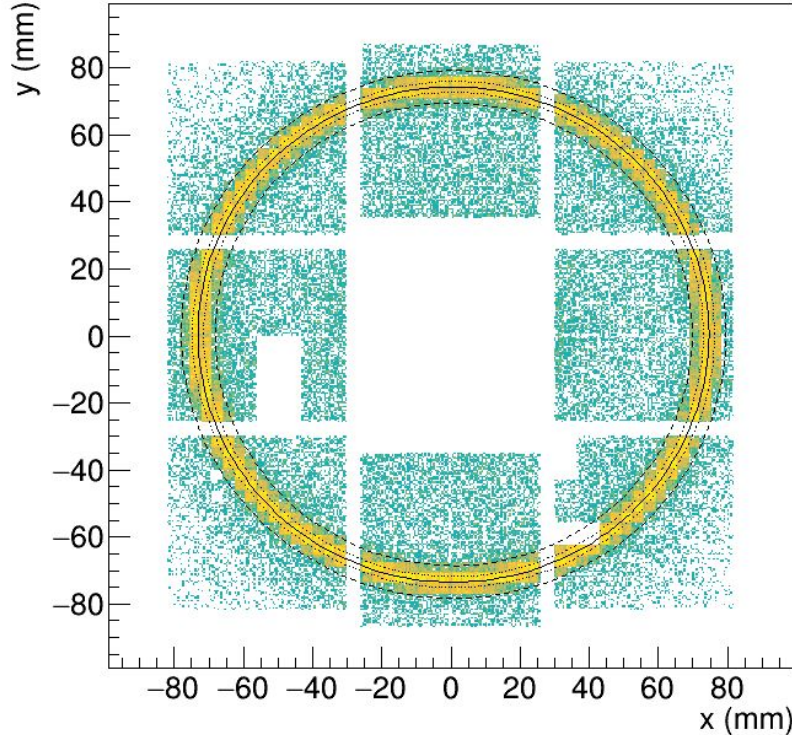


in-time (40 ns window) background is $\sim 10x$ larger than out-of-time (40 ns window) background (mostly DCR) | origin still unclear | to be understood

Background studies

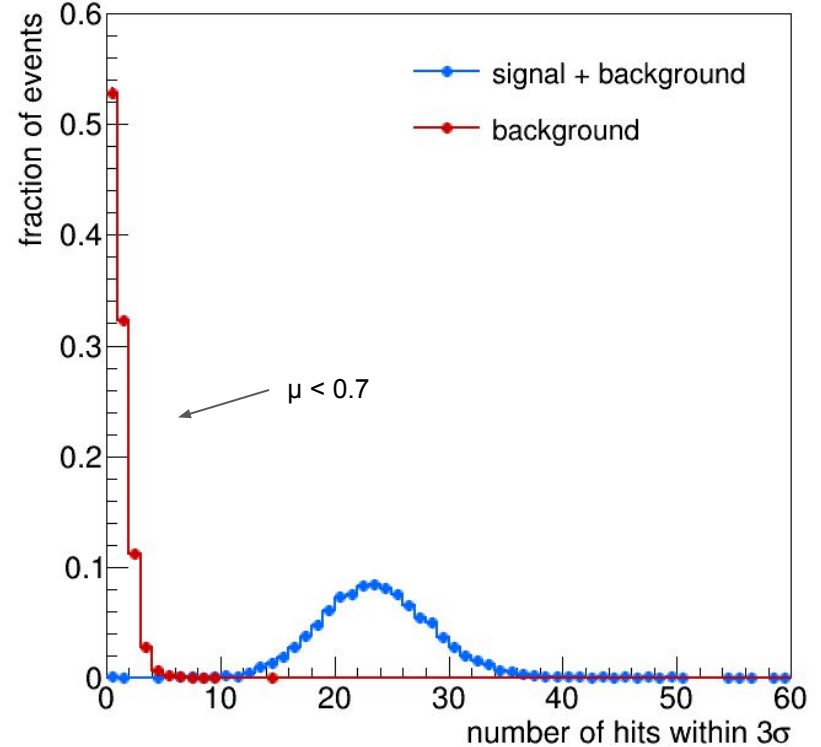
there is often one background hit in the ring, this will impact resolution

11.5 GeV/c negative beam, $n = 1.02$ aerogel (accumulated events)



2D fit to accumulated data with realistic model (ring + background)

event-by-event distribution of hits in the ring



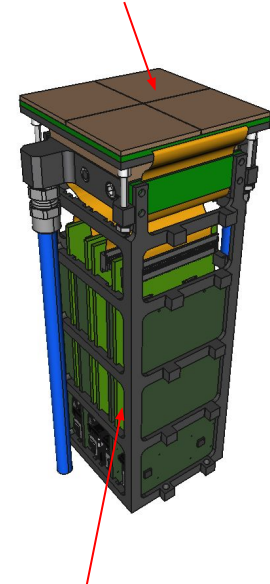
background in ring region estimated with data taken without aerogel

2023 test beam at CERN-PS

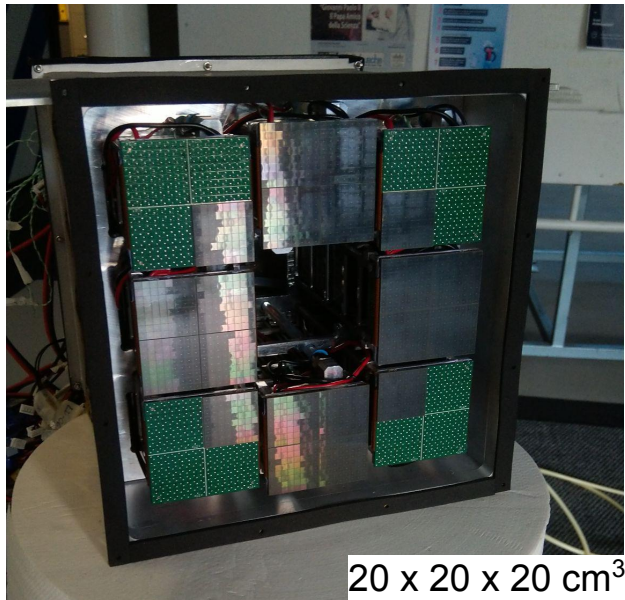
successful beam test with prototype SiPM photodetector units (CERN-PS, ended on 18th October)

PDU

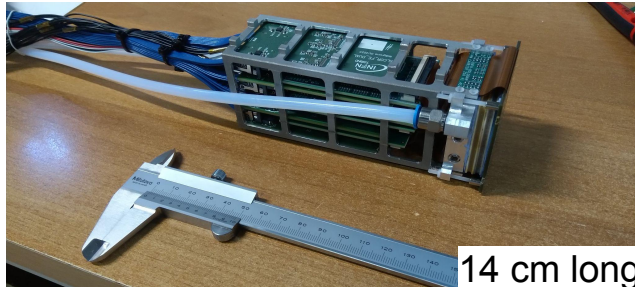
4x SiPM matrix arrays
(256 channels)



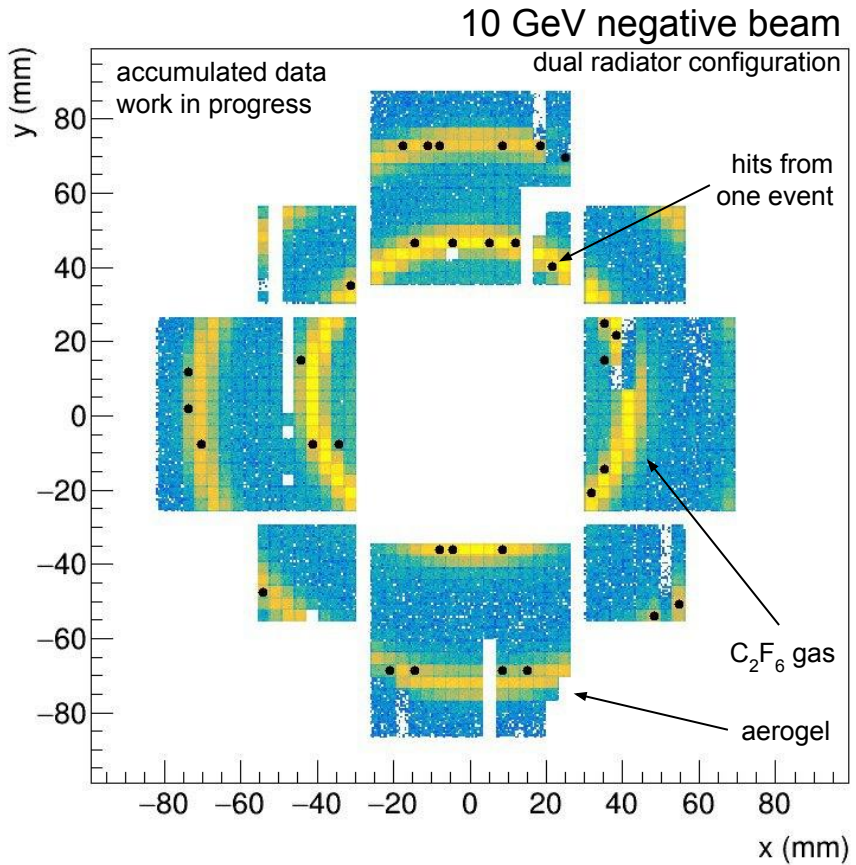
front-end electronics
(ALCOR ASIC inside)



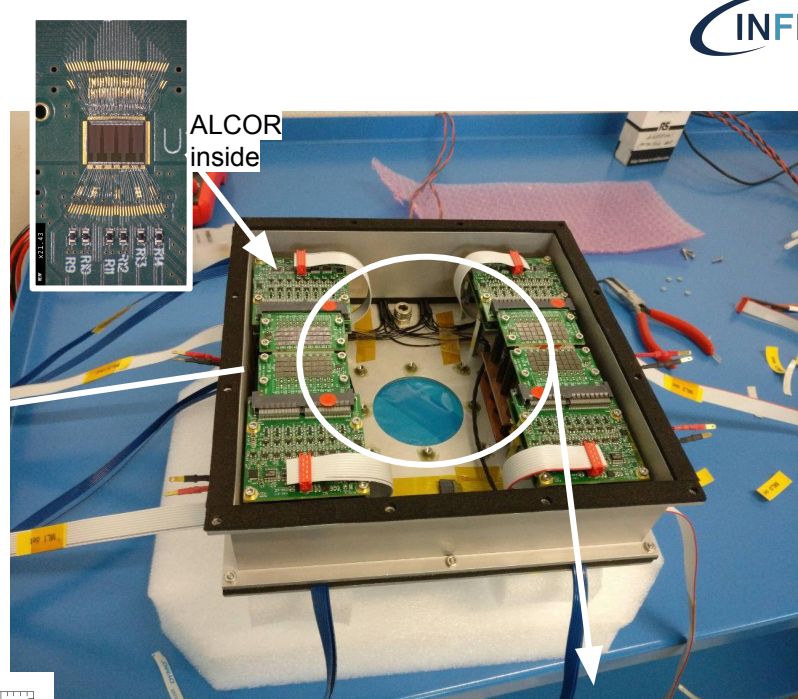
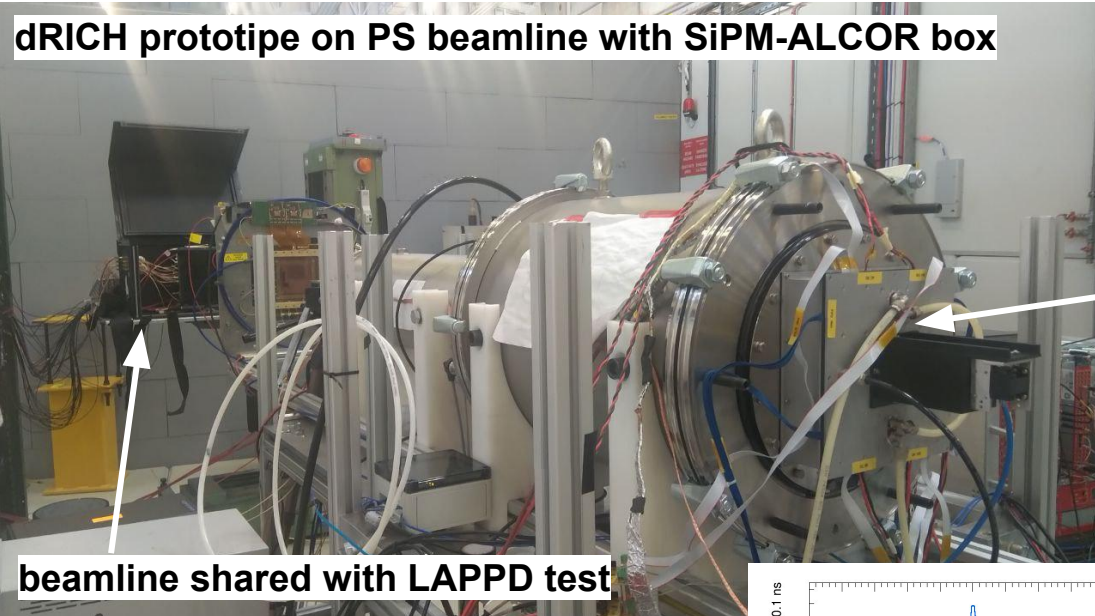
20 x 20 x 20 cm³



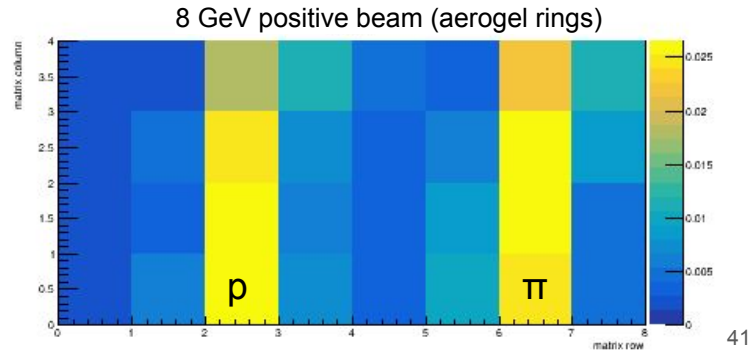
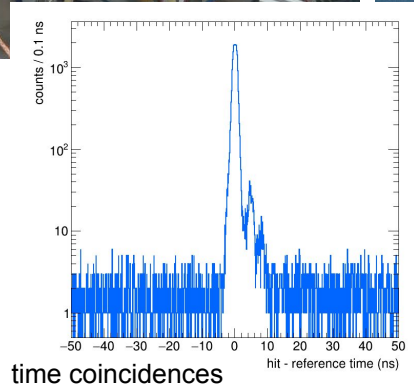
14 cm long



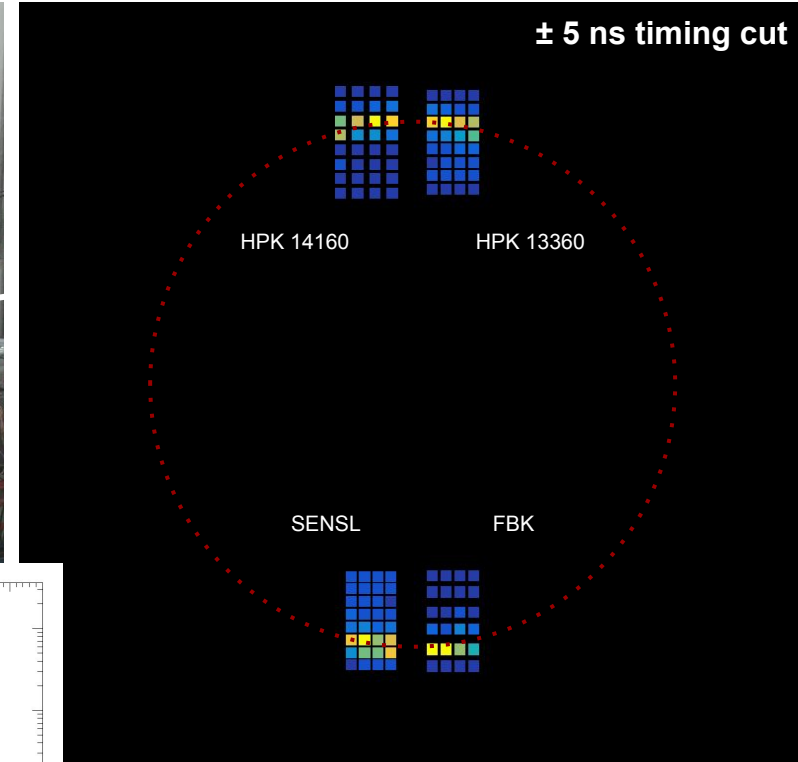
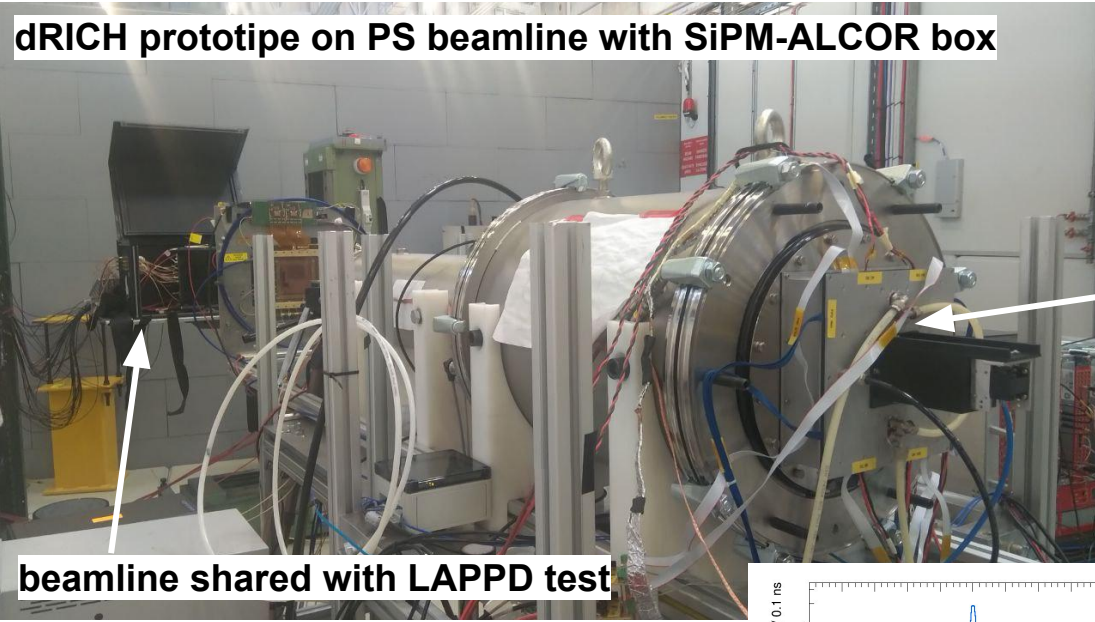
2022 test beam at CERN-PS



successful operation of SiPM
irradiated (with protons up to 10^{10})
 and annealed (in oven at 150 C)

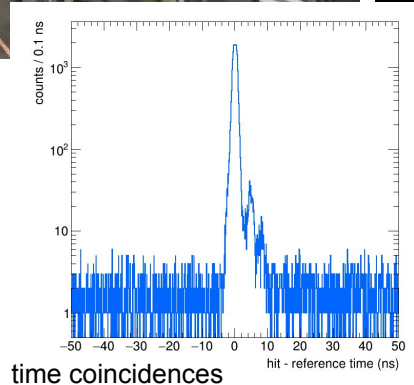


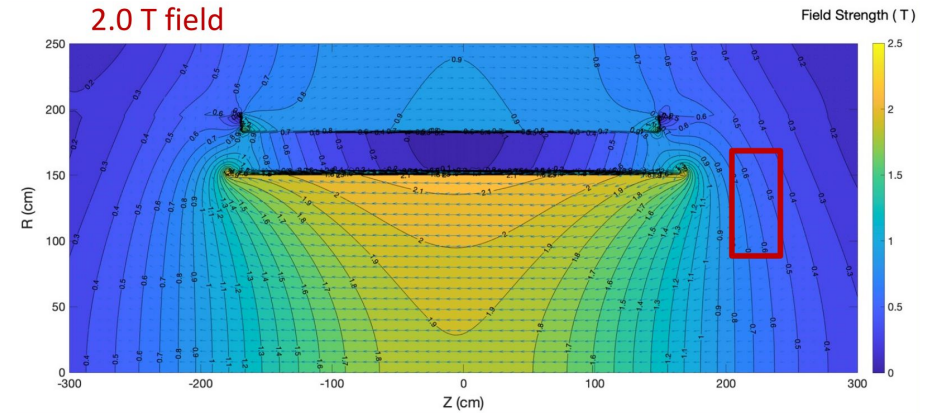
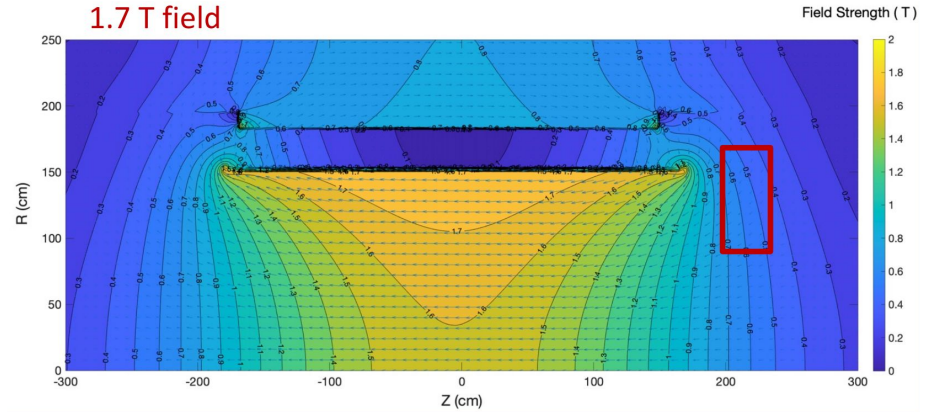
2022 test beam at CERN-PS



8 GeV negative beam (aerogel rings)

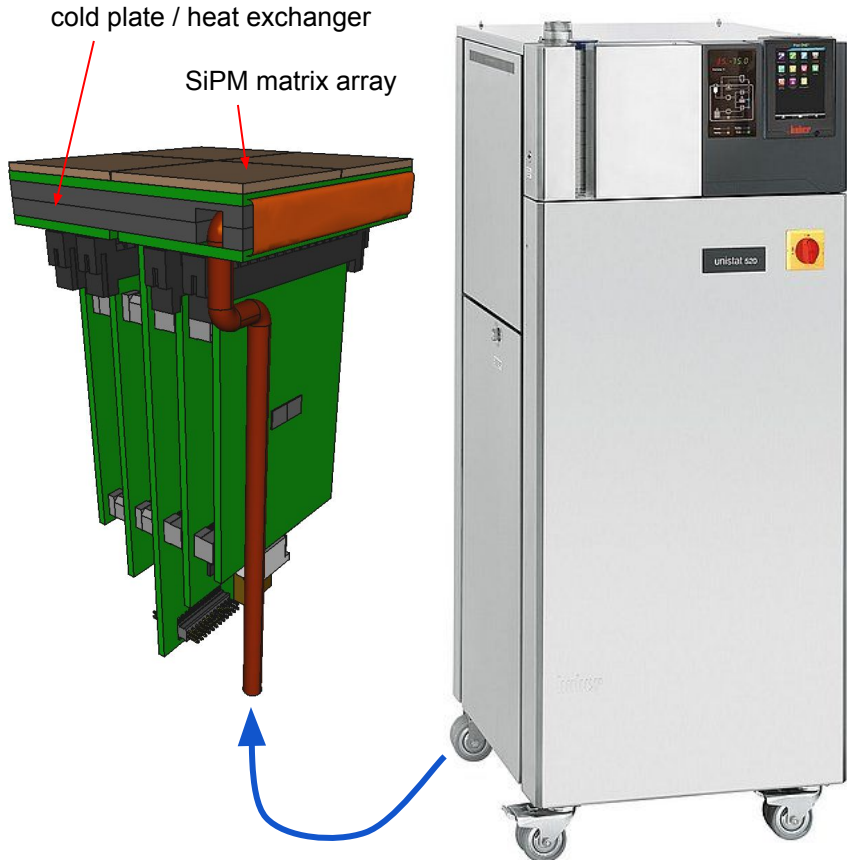
successful operation of SiPM
irradiated (with protons up to 10^{10})
 and annealed (in oven at 150 C)





non-uniform, strong magnetic field ~ 0.7 T
field lines \sim parallel to photodetector surface

SiPM cooling for low-temperature operation ($-30\text{ }^{\circ}\text{C}$ or lower)



external chiller with fluid recirculation (ie. siliconic oil)
 the chiller here one is just a commercial example
cooling and heating capacity
 could use heating capability for annealing? must be demonstrated to be feasible
 cooling capacity at $-40\text{ }^{\circ}\text{C}$ is large (1.5 kW)

huber

° General & Temperature Control

Temperature range $-55...250\text{ }^{\circ}\text{C}$

Temperature stability $\pm 0,01\text{ K}$

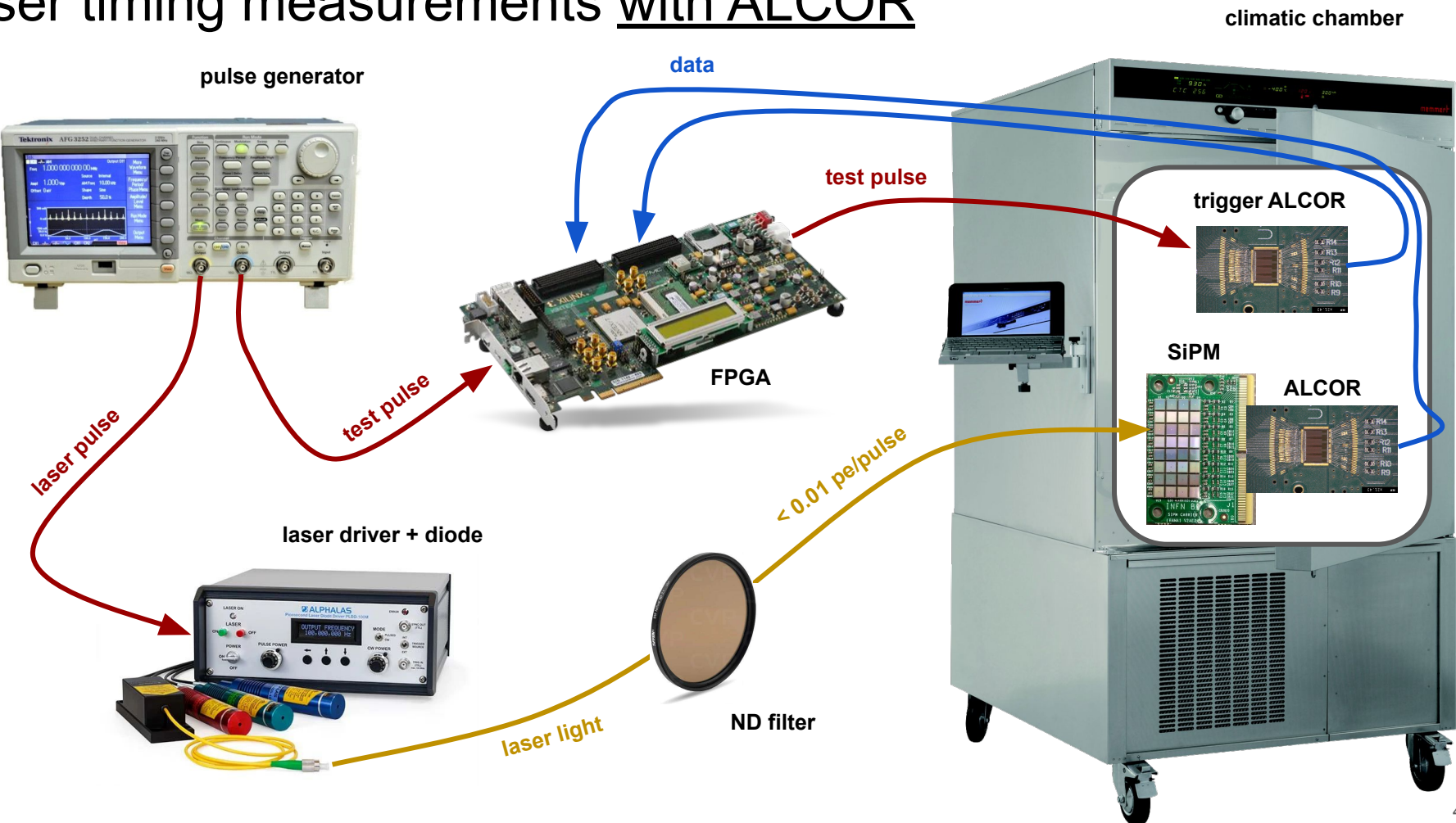
⚙ Heating / cooling capacity

Heating capacity 6 kW

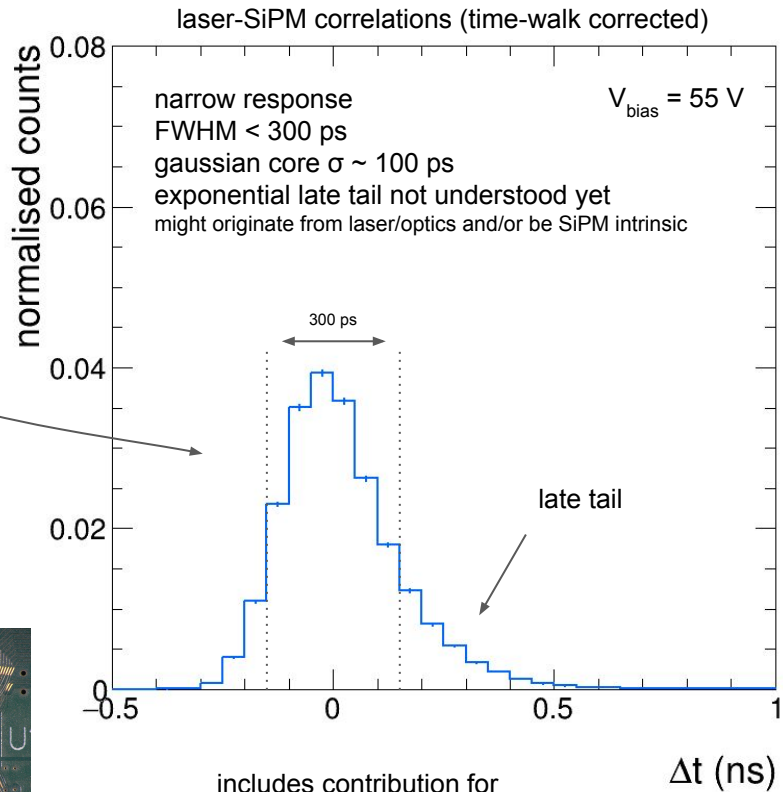
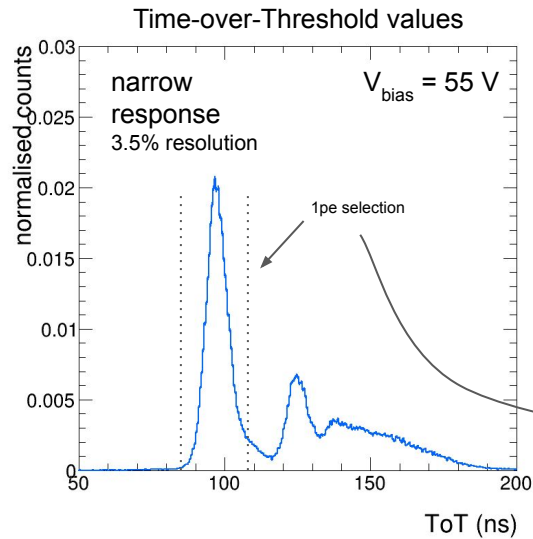
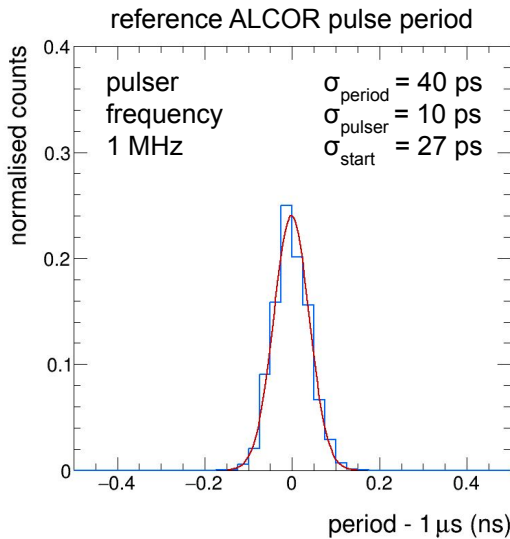
Cooling capacity

	250	200	100	20	0	-20	-40	-50	$^{\circ}\text{C}$
	6	6	6	6	6	4,2	1,5	0,65	kW

Laser timing measurements with ALCOR



Laser timing measurements with ALCOR



includes contribution for
laser-ALCOR synchronization
measured to be $\sigma_{\text{sync}} = 30 \text{ ps}$
and reference time resolution
measured to be $\sigma_{\text{start}} = 27 \text{ ps}$

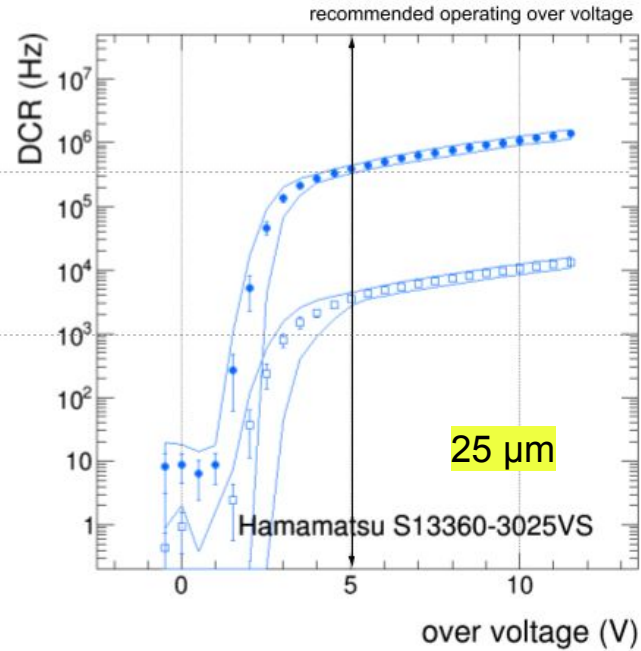
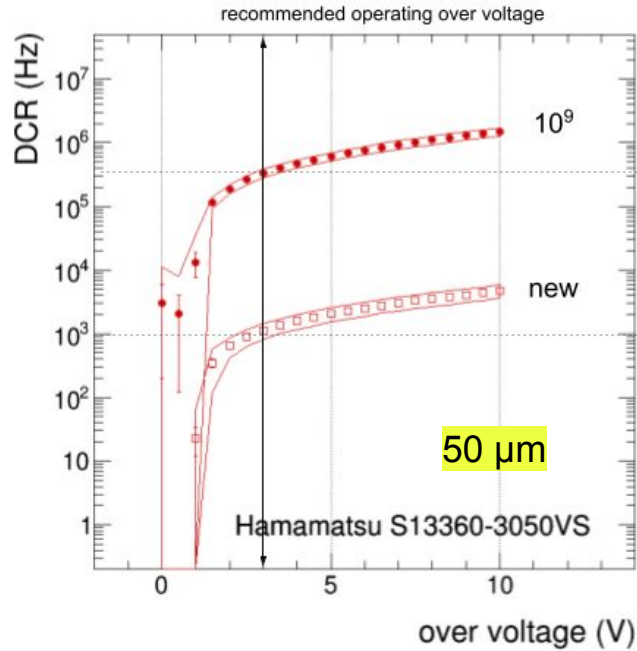
laser-SiPM signal synchronisation by sending test pulse to reference ALCOR

- to measure laser pulse t_{start}
- with 50 ps LSB TDC
- in synch with ALCOR readout

measure time coincidences Δt between reference and ALCOR reading SiPM



Small vs. large SPAD sensors



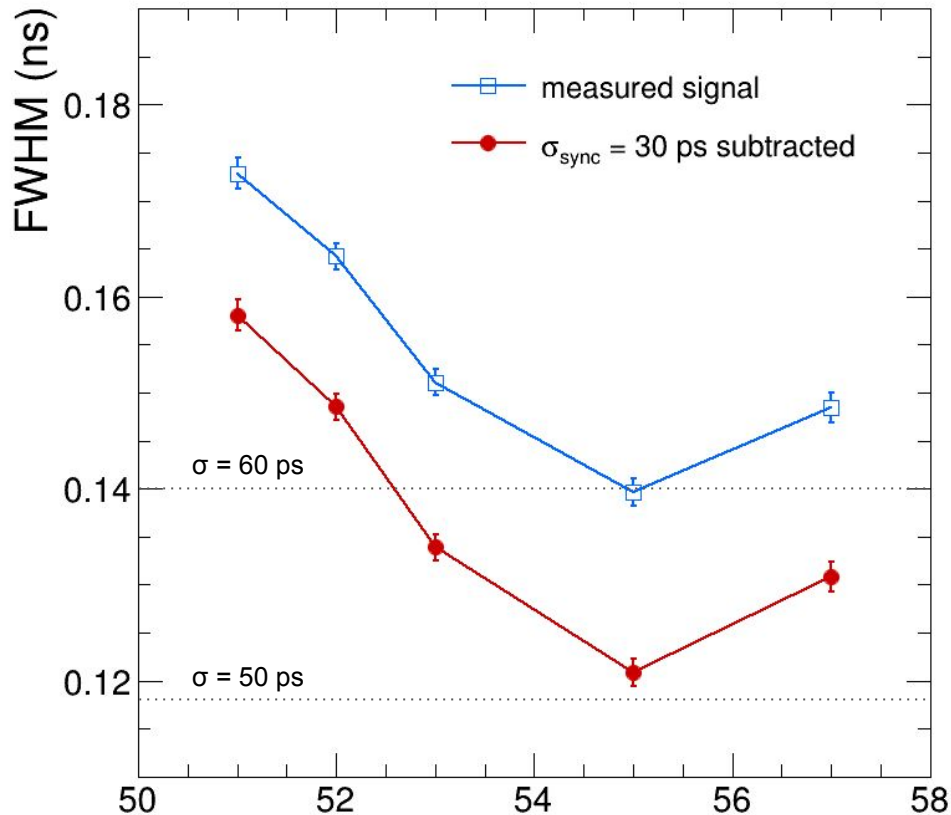
sensors with **small SPADs** have lower SNR also after irradiation

small SPAD sensors are not radiation harder for single-photon applications (RICH)

- **sensors operated at Hamamatsu recommended over-voltage**
 - [datasheet] 50 μm sensors have 40% PDE, 25 μm have 25%
 - [measured] 50 μm sensors have lower DCR than 25 μm when new
 - [measured] both sensors have similar DCR after irradiation

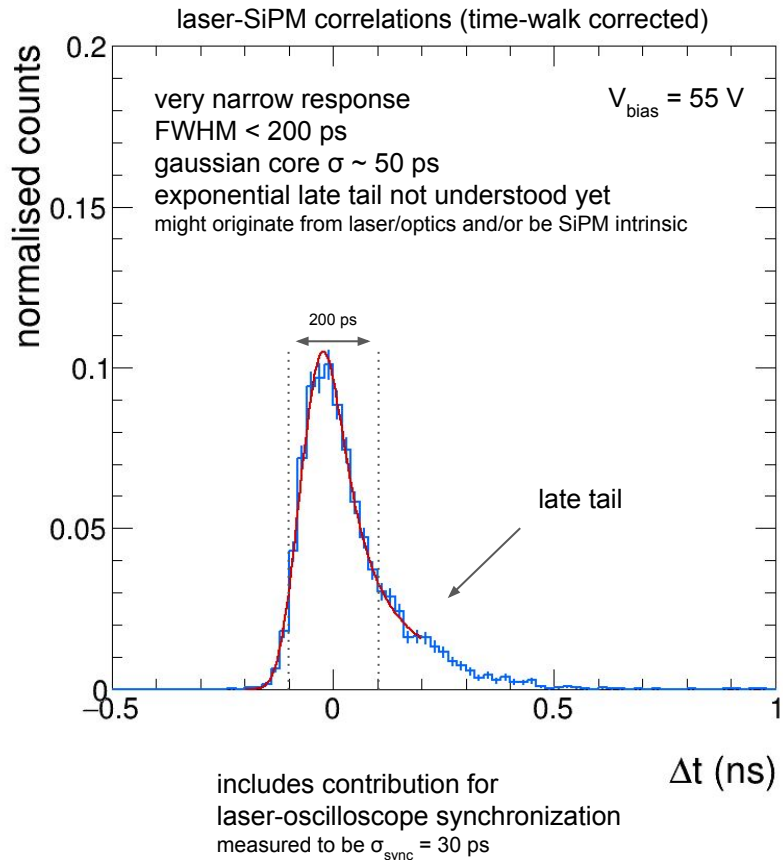
similar results and conclusions obtained with SENSL sensors

Laser timing measurements with oscilloscope

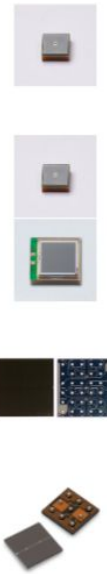


approaching $\sigma_t = 50$ ps time resolution
 will soon measure effect of radiation damage on σ_t

bias voltage (V)



Commercial SiPM sensors and FBK prototypes




board	sensor	uCell (μm)	V _{bd} (V)	PDE (%)	DCR (kHz/mm ²)	window	notes
HAMA1	S13360 3050VS	50	53	40	55	silicone	legacy model Calvi et. al
	S13360 3025VS	25	53	25	44	silicone	legacy model smaller SPAD
HAMA2	S14160 3050HS	50	38	50		silicone	newer model lower V _{bd}
	S14160 3015PS	15	38	32	78	silicone	smaller SPADs radiation hardness
SENSL	MICROFJ 30035	35	24.5	38	50	glass	different producer and lower V _{bd}
	MICROFJ 30020	20	24.5	30	50	glass	the smaller SPAD version
BCOM	AFBR S4N33C013	30	27	43	111	glass	commercially available FBK-NUVHD

PHOTON IS OUR BUSINESS

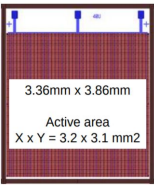


ON Semiconductor®





NUV-HD-CHK





3.36mm x 3.86mm
Active area
X x Y = 3.2 x 3.1 mm²

NUV-HD big cells

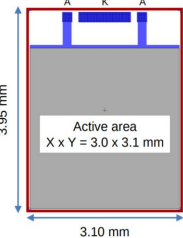
Technology similar to NUV-HD-Cryo
Optimized for single photon timing

- Cell pitch 40 μm
- High PDE > 55%
- Primary DCR @ +24°C ~ 50 kHz/mm²
- Correlated noise 35% @ 6 V

October 5, 2020
FBK - Confidential




NUV-HD-RH




3.95 mm
Active area
X x Y = 3.0 x 3.1 mm
3.10 mm

NUV-HD-RH

Technology under development
optimized for radiation hardness in
HEP experiments

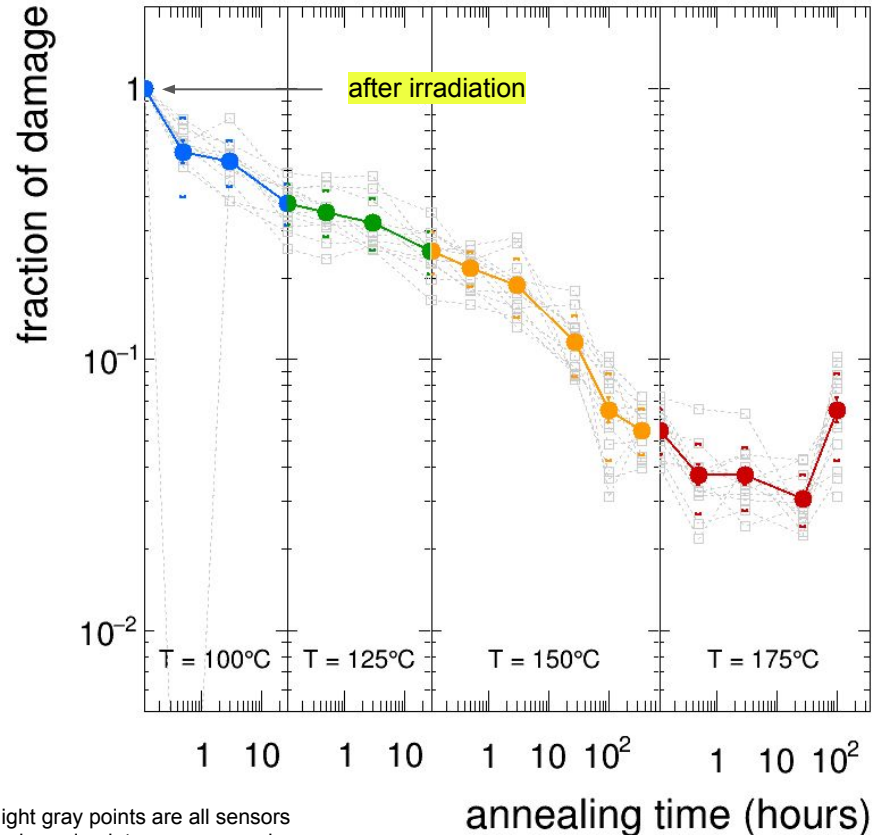
- Cell pitch 15 μm with high fill factor
- Fast recovery time – reduced cell occupancy
Tau recharge < 15 ns
- Primary DCR @ +24°C ~ 40 kHz/mm²
- Correlated noise 10% @ 6 V

October 5, 2020
FBK - Confidential


multiple producers: different technologies, SPAD dimensions, V_{bd}, electric field ...

Detailed studies of SiPM online self-annealing

online self-annealing with reverse bias



light gray points are all sensors
coloured points are averaged over sensors
coloured brackets is the RMS

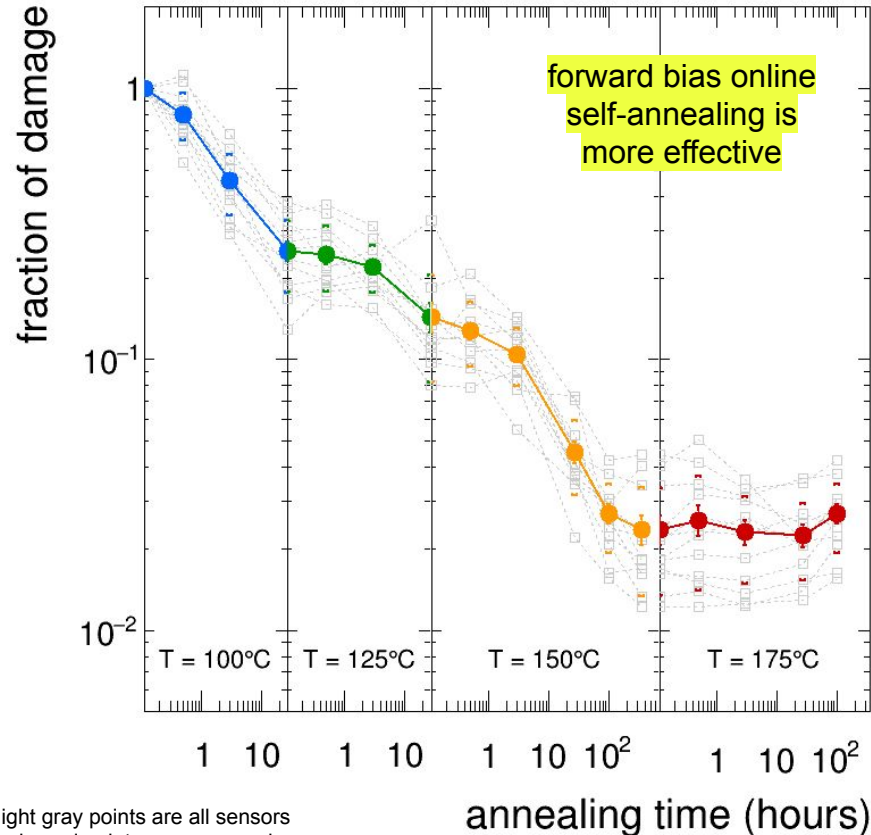
test on a large number of proton irradiated sensors how much damage is cured as a function of temperature and time

in this study, the same sensors have undergone self-annealing in increasing temperature steps and increasing integrated time steps

- started with T = 100 C annealing
 - performed 4 steps up to 30 hours integrated
- followed by T = 125, 150 and 175 C

Detailed studies of SiPM online self-annealing

online self-annealing with forward bias



light gray points are all sensors
coloured points are averaged over sensors
coloured brackets is the RMS

test on a large number of proton irradiated sensors how much damage is cured as a function of temperature and time

in this study, the same sensors have undergone self-annealing in increasing temperature steps and increasing integrated time steps

- started with T = 100 C annealing
 - performed 4 steps up to 30 hours integrated
- followed by T = 125, 150 and 175 C

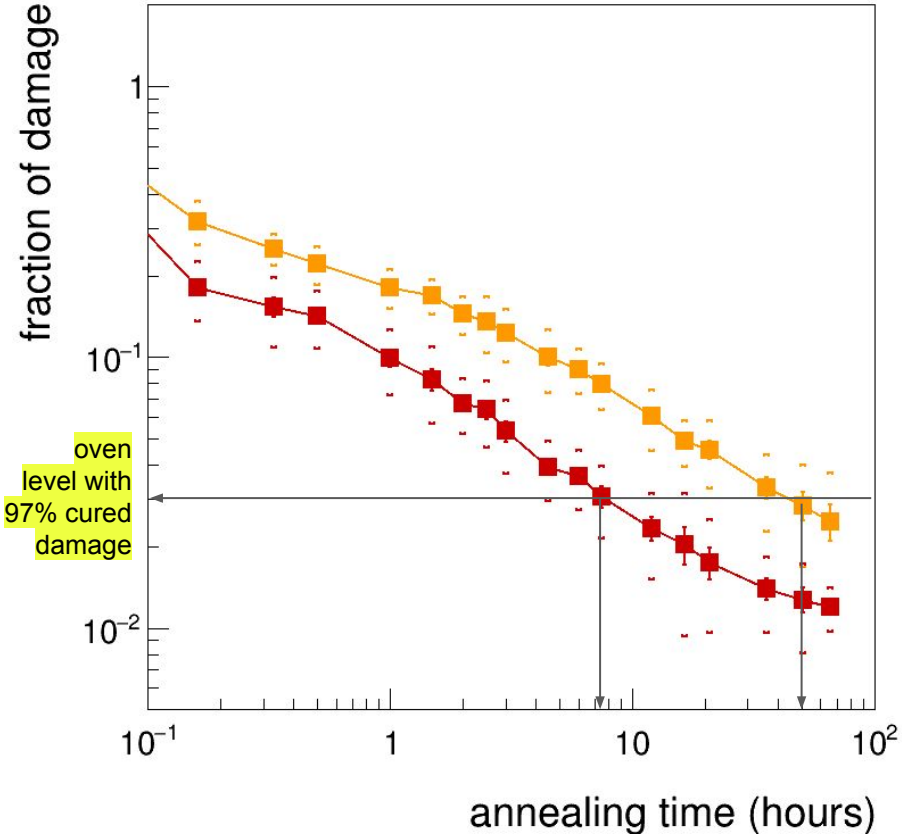
fraction of residual damage seems to saturate at 2-3%

after ~ 300 hours at T = 150 C

continuing at higher T = 175 C seems not to cure more than that

Automated multiple SiPM online self-annealing

online self-annealing with forward bias



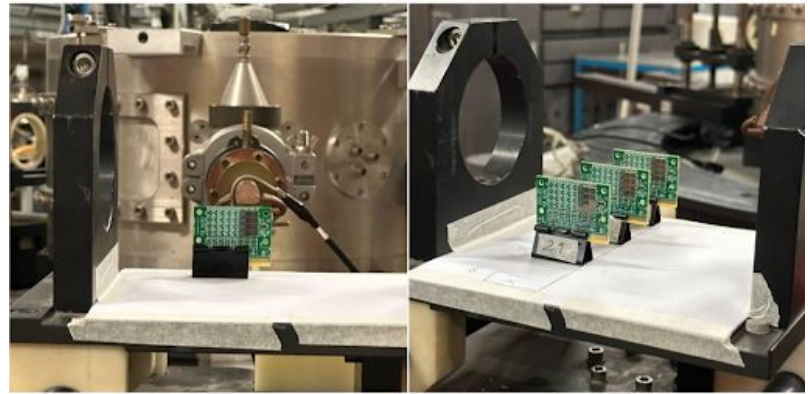
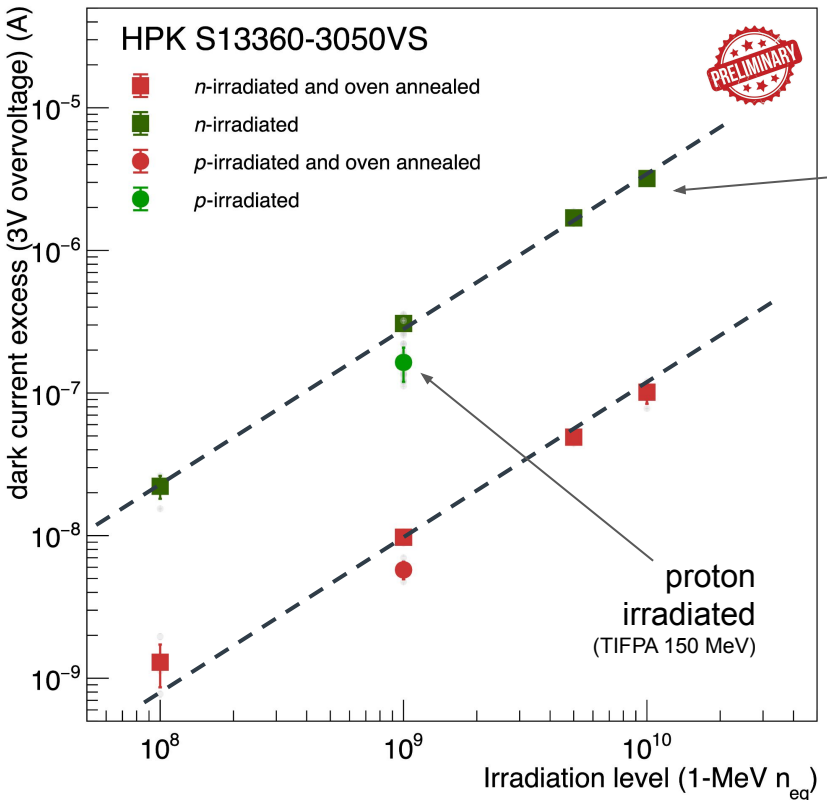
comparison between two annealing temperatures

both reach and exceed the oven limit of ~ 2-3% residual damage

- at T = 175 C
 - there seems to be a faster “sudden” cure
 - followed by a similar rate of reduction with time
- oven-level annealing reached faster at T = 175 C
 - < 10 hours integrated
- oven-level annealing reached at T = 150 C
 - < 100 hours integrated

Preliminary comparison of neutron vs. proton damage

neutrons from Be(d,n) reaction with 4 MeV deuteron beam

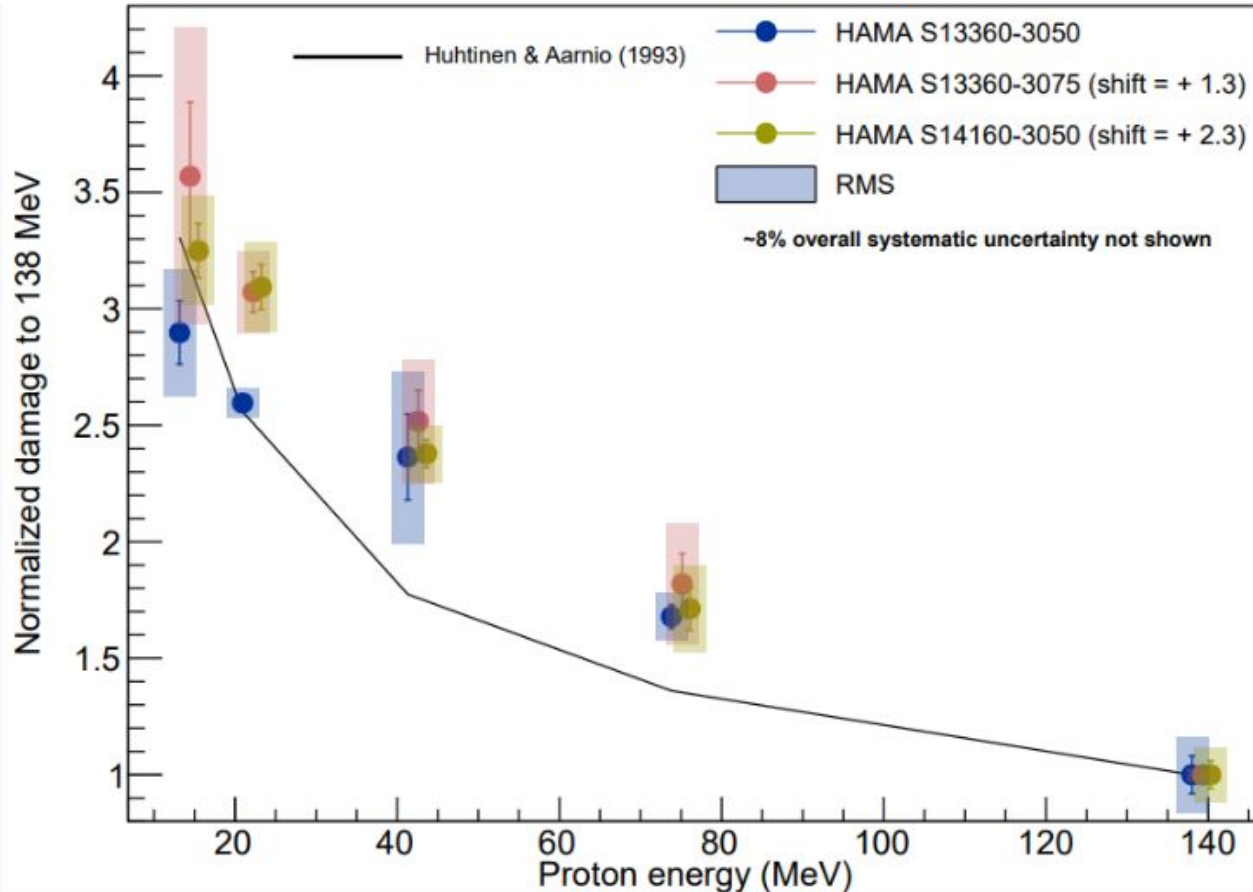


we have very preliminary results on comparison between neutron and proton damage which indicate that

neutron damage is larger after same n_{eq} fluence
 using NIEL scaling for normalisation

by approximately a factor of 2x
 we use a 10x safety factor for radiation damage estimates

Preliminary proton vs. energy damage



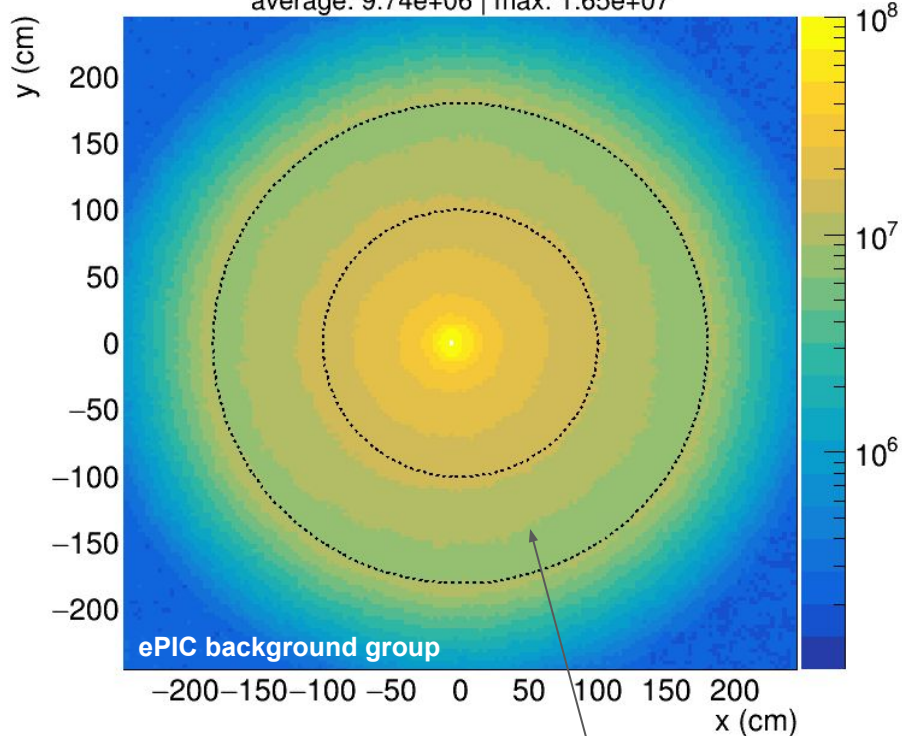
we have very preliminary results on comparison between of proton damage vs. proton energy to NIEL hypothesis which indicate that the scaling is valid within 30-50%

using NIEL scaling for normalisation

Radiation damage estimates

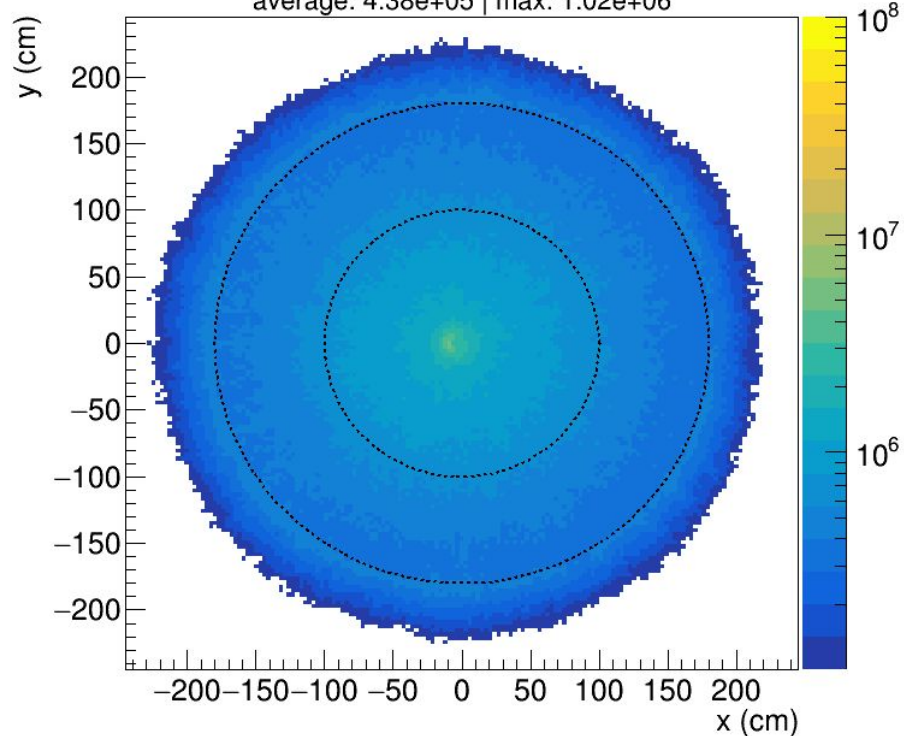
1 MEQ neutron equivalent fluence ($\text{cm}^{-2}/\text{fb}^{-1}$)
 minimum-bias PYTHIA e+p events at 10×275 GeV

average: 9.74×10^6 | max: 1.65×10^7



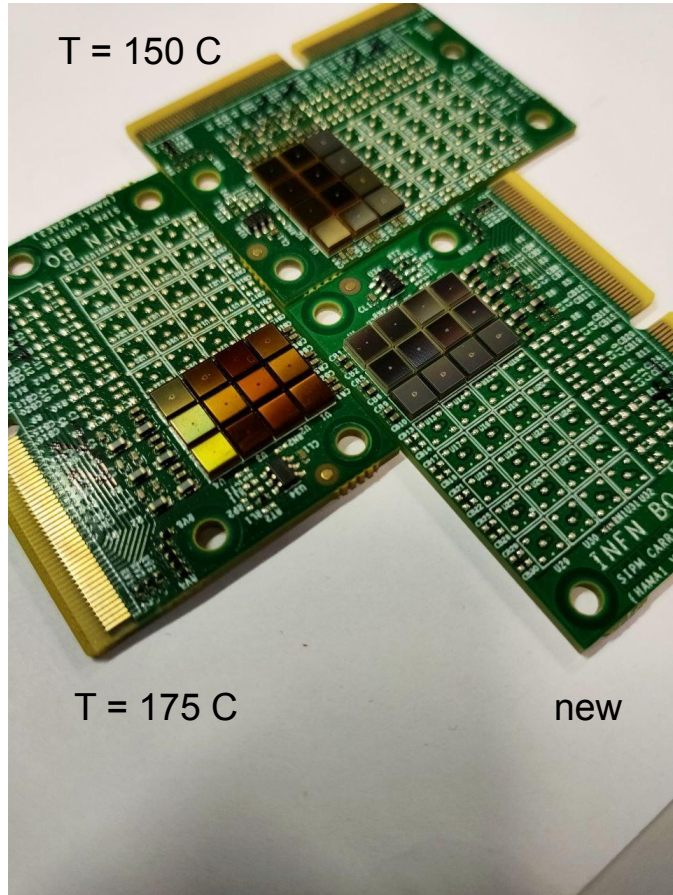
1 MEQ neutron equivalent fluence ($\text{cm}^{-2}/\text{fb}^{-1}$)
 275 GeV proton beam+gas events @ 35 kHz

average: 4.38×10^5 | max: 1.02×10^6



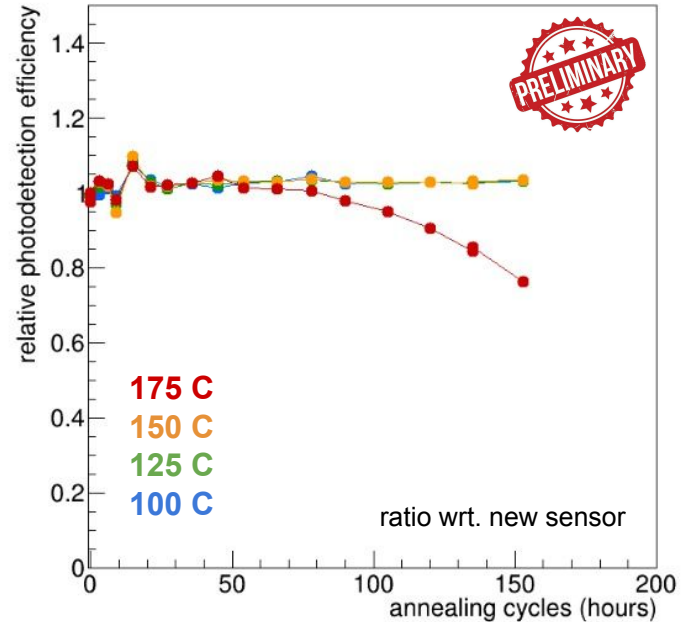
max fluence = 1.75×10^7 neq/ fb^{-1} at the location of dRICH photosensors

Detailed studies of SiPM online self-annealing



after many hours of online annealing

we noticed alterations on the SiPM windows
in particular in one board that underwent
500 hours of online annealing at $T = 175\text{ C}$
the sensors appear "yellowish" when compared to new

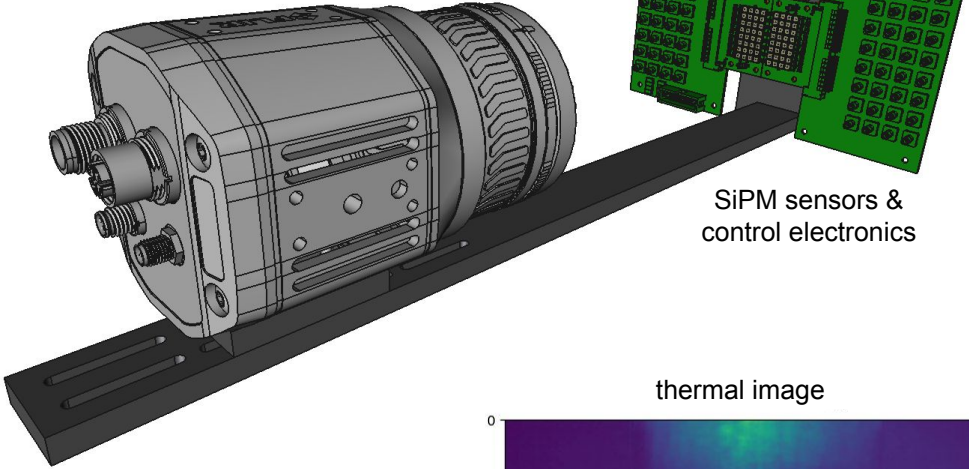


detailed studies are ongoing, preliminary results indicate efficiency loss after 100 hours of annealing at $T = 175\text{ C}$. **lower temperatures unaffected up to 150 hours**

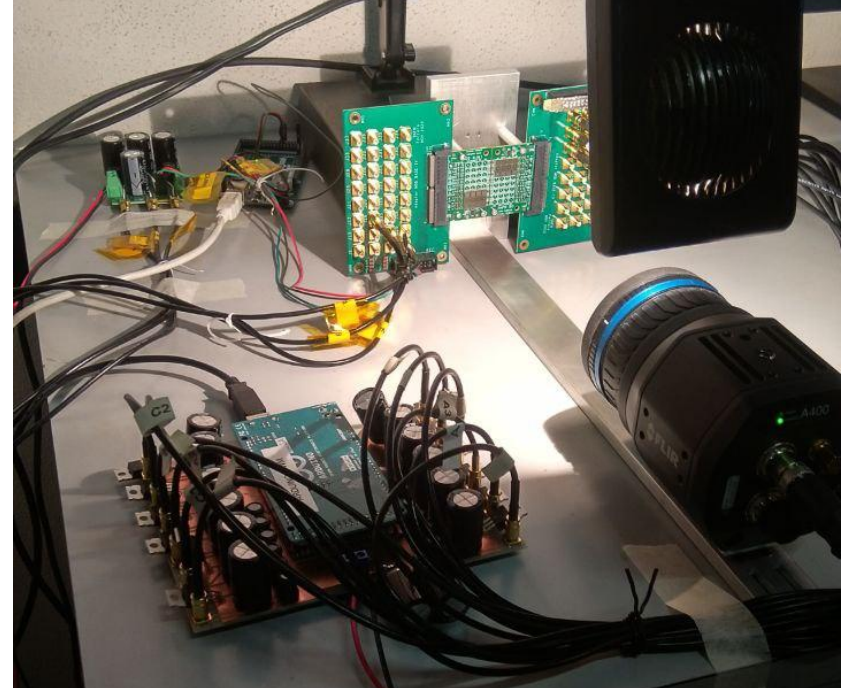
Automated multiple SiPM online self-annealing

system for online self-annealing with temperature monitor and control of each individual SiPM

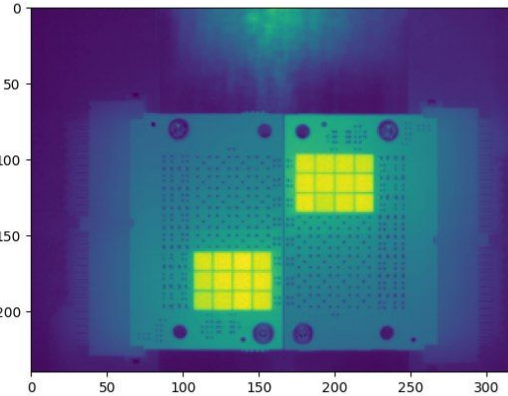
thermal camera



SiPM sensors & control electronics



thermal image

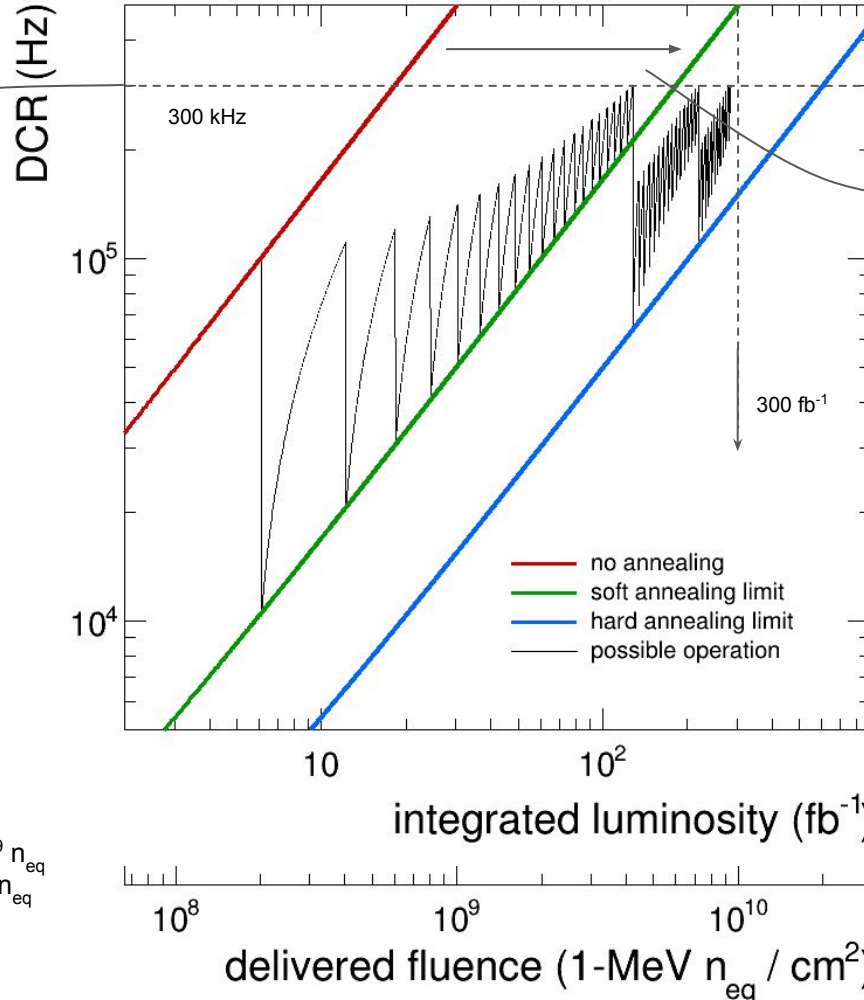
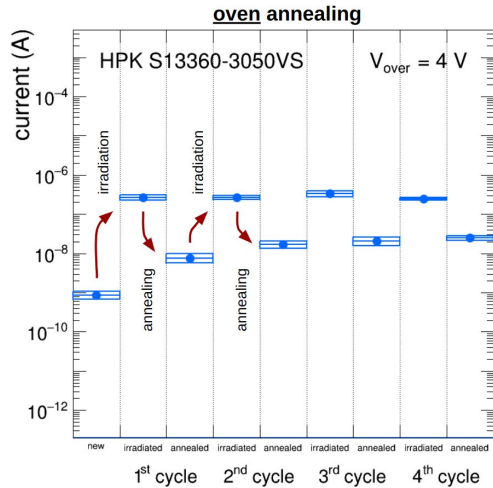


monitor and logging system



Ageing model

max acceptable DCR for
Physics performance
~ 10 noise hits / sector **within 500 ps**



in-situ annealing
significantly extends
SiPM lifetime

up to 300 fb⁻¹ without need
of touching/replacing SiPM
working on optimisation of
annealing protocol, maybe one
could reach beyond that

these predictions are according to
present knowledge / tested solutions
there are more handles to
further mitigate DCR
lower Vover, 3V
lower T operation -40 C or below

model input from R&D measurements (up to 2022)

- DCR increase: 500 kHz/10⁹ n_{eq}
- residual DCR (online annealing): 50 kHz/10⁹ n_{eq}
- residual DCR (oven annealing): 15 kHz/10⁹ n_{eq}

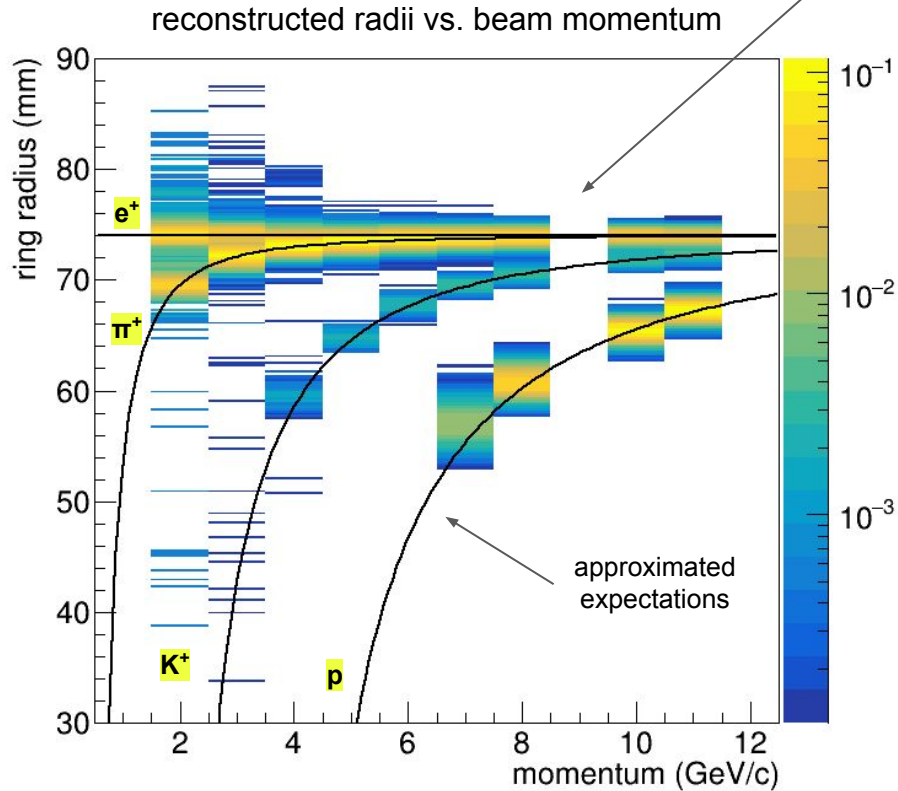
1-MeV neq fluence from background group

- 1.75 10⁷ n_{eq} / fb^{-1}
- with an extra 2x safety factor

Beam momentum scan

positive particles, aerogel only

something went wrong with the beam configuration for 9 GeV (that's a pity, data seems not good)



reconstructed ring radius at 10 GeV/c beam momentum

